

16-Bit Sigma-Delta ADCs

FEATURES

HT7705: Two Fully Differential Input Channel ADCs HT7706: Three Pseudo Differential Input Channel ADCs 16 Bits No Missing Codes 0.003% Nonlinearity
Programmable Gain Front End
Gains from 1 to 128
Three-Wire Serial Interface
SPI™, QSPI™, MICROWIRE™ and DSP Compatible
Schmitt Trigger Input on SCLK
Ability to Buffer the Analog Input
2.7 V to 3.3 V or 4.75 V to 5.25 V Operation
Power Dissipation 1 mW max @ 3 V
Standby Current 8 µA max
16-Lead DIP, 16-Lead SOIC and TSSOP Packages

GENERAL DESCRIPTION

The HT7705/HT7706 are complete analog front ends for low frequency measurement applications. These two-/three-channel devices can accept low level input signals directly from a transducer and produce a serial digital output. They employ a sigmadelta conversion technique to realize up to 16 bits of no missing codes performance. The selected input signal is applied to a proprietary programmable gain front end based around an analog modulator. The modulator output is processed by an on-chip digital filter. The first notch of this digital filter can be programmed via an on-chip control register allowing adjustment of the filter cutoff and output update rate.

The HT7705/HT7706 operate from a single 2.7 V to 3.3 V or 4.75 V to 5.25 V supply. The HT7705 features two fully differential analog input channels while the HT7706 features three pseudo differential input channels. Both devices feature a differential reference input. Input signal ranges of 0 mV to +20 mV through 0 V to +2.5 V can be incorporated on both devices when operating with a V_{DD} of 5 V and a reference of 2.5 V. They can also handle bipolar input signal ranges of ± 20 mV through ± 2.5 V, which are referenced to the AIN(–) inputs on the HT7705 and to the COMMON input on the HT7706. The HT7705/HT7706, with 3 V supply and a 1.225 V reference, can handle unipolar input signal ranges of 0 mV to +1.225 V. Its bipolar input signal ranges are ± 10 mV through ± 1.225 V. The HT7705/HT7706 thus perform all signal conditioning and conversion for a two- or three-channel system.

The HT7705/HT7706 are ideal for use in smart, microcontroller or DSP-based systems. They feature a serial interface that can be configured for three-wire operation. Gain settings, signal polarity and update rate selection can be configured in software

*Protected by U.S. Patent Number 5,134,401.

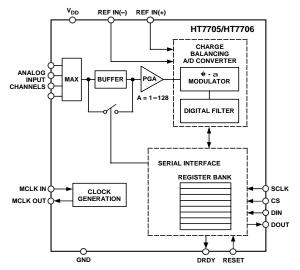
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MICROWIRE is a trademark of National Semiconductor.

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FUNCTIONAL BLOCK DIAGRAM



using the input serial port. The part contains self-calibration and system calibration options to eliminate gain and offset errors on the part itself or in the system.

CMOS construction ensures very low power dissipation, and the power-down mode reduces the standby power consumption to 20 μ W typ. These parts are available in a 16-lead, 0.3 inch-wide, plastic dual-in-line package (DIP), a 16-lead wide body (0.3 inch) small outline (SOIC) package and also a low profile 16-lead TSSOP.

PRODUCT HIGHLIGHTS

- 1. The HT7705/HT7706 consumes less than 1 mW at 3 V supplies and 1 MHz master clock, making it ideal for use in low power systems. Standby current is less than 8 μ A.
- The programmable gain input allows the HT7705/HT7706 to accept input signals directly from a strain gage or transducer, removing a considerable amount of signal conditioning.
- 3. The HT7705/HT7706 is ideal for microcontroller or DSP processor applications with a three-wire serial interface reducing the number of interconnect lines and reducing the number of opto-couplers required in isolated systems.
- 4. The part features excellent static performance specifications with 16 bits, no missing codes, $\pm 0.003\%$ accuracy and low rms noise (<600 nV). Endpoint errors and the effects of temperature drift are eliminated by on-chip calibration options, which remove zero-scale and full-scale errors.



$ \begin{array}{c} \operatorname{STATLPERFORMANCE} \\ \operatorname{Output Noise} \\ \operatorname{Dutput Noise} \\ $	Parameter	B Version ¹	Units	Conditions/Comments
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$ \begin{array}{c} \text{Common-Mode 60 Hz Rejection2} \\ \text{Absolute/Common-Mode AEF IN Voltage2,9} \\ \text{Absolute/Common-Mode AIN Voltage2,9} \\ \text{Absolute/Common-Mode AIN Voltage2,9} \\ \text{Absolute/Common-Mode AIN Voltage2,9} \\ \text{Absolute/Common-Mode AIN Voltage2,9} \\ \text{AlN DC Input Current2} \\ \text{AIN DD Input Current2} \\ \text{AIN DIfferential Voltage Range10} \\ \text{AIN Differential Voltage Range10} \\ \text{AIN Differential Voltage Range10} \\ \text{AIN put Sampling Rate, fs} \\ \text{Reference Input Range} \\ \text{Reference Input Range} \\ \text{Reference Input Range} \\ \text{Ref IN(+) - REF IN(-) Voltage} \\ \text{REF IN(+) - REF IN(-) Voltage} \\ \text{AII Input Sampling Rate, fs} \\ Cause f for the form of the form $				
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Absolute/Common-Mode AIN Voltage $V_{up} + 30 \text{ mV}$ GND + 50 mV $V_{po} - 1.5 \text{ V}$ AIN DC Input Current2 AIN Sampling Capacitance2 AIN Differential Voltage Range10 $V_{up} - 1.5 \text{ V}$ 1 10 0 to $+V_{war}/GAIN^{11}$ $\pm 0 \text{ to } V_{war}/GAIN^{11}$ $\pm 0 \text{ to } +V_{war}/GAIN^{11}$ $\pm 0 \text{ to } -REF IN(+) - REF IN(-) Voltage1/3.5+V \text{ min/max}Uniplate Ange (B/U Bit of Setup Register = 1)Bipolar Input Range (B/U Bit of Setup Register = 0)For Gains of B to 128+V_{00} = 2.7 \text{ V to } 3.3 \text{ V} V_{Rgr} = 2.5 \pm 1\% for SpecifiedPerformance+V_{00} = 4.75 \text{ V to } 5.25 \text{ V}. V_{Rgr} = 2.5 \pm 1\% for SpecifiedPerformance+V_{00} = 3.1225 \pm 1\% for SpecifiedPerformance+V_{00} = 3.1225 \pm 1\%+10 \pm 10 \pm 10 \pm 100 \text{ Voltage}+10 \pm 10 \pm 100 \text{ Voltage}+10 \pm 10 \pm 100 $	Absolute/Common-Mode REF IN Voltage ²	GND to V _{DD}		
Absolute/Common-Mode AIN Voltage ^{2,9} $GND + 50 \text{ mV}$ $V_{DD} - 1.5 \text{ V}$ $I_D = 1.5 \text{ V}$ $V_{DD} - 1.5 \text{ V}$ $AIN DC Input Current2AIN Differential Voltage Range10GND + 50 \text{ mV}V_{max}D to + V_{nep}/GAIN^{11}\pm 1/1 + 1/2 + 1$	Absolute/Common-Mode AIN Voltage ^{2, 9}	GND - 30 mV	V min	BUF Bit of Setup Register = 0
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$V_{T_{*}}$ 1.4/3 $V \min/V \max$ $V \min/V \max$ $V_{T_{*}}$ 0.8/1.4 $V \min/V \max$ $V \min/V \max$ $V_{T_{*}} - V_{T_{*}}$ 0.4/0.8 $V \min/V \max$ $V_{DD} = 3 V \text{ NOMINAL}$ SCLK Only (Schmitt Triggered Input) 1/2.5 $V \min/V \max$ $V_{DD} = 3 V \text{ NOMINAL}$ $V_{T_{*}}$ 0.4/1.1 $V \min/V \max$ $V_{DD} = 5 V \text{ NOMINAL}$ $V_{T_{*}} - V_{T_{*}}$ 0.8 $V \min/V \max$ $V_{DD} = 5 V \text{ NOMINAL}$ V_{INL_*} Input Low Voltage 0.8 $V \max$ $V_{DD} = 5 V \text{ NOMINAL}$ V_{INL_*} Input High Voltage 0.4 $V \max$ $V_{DD} = 5 V \text{ NOMINAL}$	SCLK Only (Schmitt Triggered Input)	2.0	v IIIII	
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$, , , , , , , , , , , , , , , , , , ,	1.4/3	V min/V max	VDD - 5 V NOMINAL
$ \begin{array}{cccc} V_{T_{*}}-V_{T_{*}} & 0.4/0.8 & V \min/V \max \\ SCLK \ Only (Schmit Triggered Input) & 1/2.5 & V \min/V \max \\ V_{T_{*}} & 0.4/1.1 & V \min/V \max \\ V_{T_{*}}-V_{T_{*}} & 0.375/0.8 & V \min/V \max \\ MCLK \ IN \ Only & \\ V_{INH_{*}} \ Input \ High \ Voltage & 0.8 & V \max \\ V_{INH_{*}} \ Input \ High \ Voltage & 0.4 & V \min \\ MCLK \ IN \ Only & \\ V_{INH_{*}} \ Input \ Uow \ Voltage & 0.4 & V \max \\ \end{array} $				
SCLK Only (Schmitt Triggered Input) /2.5 V min/V max $V_{DD} = 3 V NOMINAL$ V_{T-} 0.4/1.1 V min/V max $V_{DD} = 5 V NOMINAL$ V_{T-} 0.375/0.8 V min/V max $V_{DD} = 5 V NOMINAL$ MCLK IN Only 0.8 V max $V_{DD} = 5 V NOMINAL$ V _{INL} , Input Low Voltage 0.8 V max $V_{DD} = 5 V NOMINAL$ MCLK IN Only 0.8 V max $V_{DD} = 5 V NOMINAL$ VINL, Input Low Voltage 0.4 V max $V_{DD} = 5 V NOMINAL$				
$ \begin{array}{cccccccccccccccccccccccccccccccccccc$				$V_{DD} = 3 V NOMINAL$
$V_{T_*} - V_{T}$ 0.375/0.8 V min/V max MCLK IN Only 0.8 V max V_{INL_*} Input Low Voltage 0.8 V max V_{INL_*} Input High Voltage 3.5 V min MCLK IN Only 0.4 V max	V _{T+}	1/2.5	V min/V max	
MCLK IN Only Vml VDD = 5 V NOMINAL VINL, Input Low Voltage 0.8 V max VINL, Input High Voltage 3.5 V min MCLK IN Only V V VINL, Input Low Voltage 0.4 V max	V _{T-}			
V _{INL} , Input Low Voltage 0.8 V max V _{INL} , Input High Voltage 3.5 V min MCLK IN Only V _{INL} , Input Low Voltage 0.4		0.375/0.8	V min/V max	
V _{INH} , Input High Voltage 3.5 V min MCLK IN Only 0.4 V max				$V_{DD} = 5 V NOMINAL$
MCLK IN Only V _{INL} Input Low Voltage 0.4 V max				
V _{INL} , Input Low Voltage 0.4 V max		3.5	V min	
		0.4	V may	
	V , Input High Voltage	0.4	v IIIax	
· ,	. , input ingli voltage	I	I	I



	I	1	1
Parameter	B Version ¹	Units	Conditions/Comments
$\begin{array}{c} \mbox{LOGIC OUTPUTS (Including MCLK OUT)} \\ V_{OL}, Output Low Voltage \\ V_{OL}, Output Low Voltage \\ V_{OH}, Output High Voltage \\ V_{OH}, Output High Voltage \\ Floating State Leakage Current \\ Floating State Output Capacitance^{13} \\ Data Output Coding \end{array}$	$\begin{array}{c} 0.4\\ 0.4\\ 4\\ V_{DD}-0.6\\ \pm 10\\ 9\\ Binary\\ Offset Binary \end{array}$	V max V max V min V min μA max pF typ	$\begin{split} I_{\text{SINK}} &= 800 \ \mu\text{A Except for MCLK OUT.}^{12} \ V_{\text{DD}} = 5 \ V. \\ I_{\text{SINK}} &= 100 \ \mu\text{A Except for MCLK OUT.}^{12} \ V_{\text{DD}} = 3 \ V. \\ I_{\text{SOURCE}} &= 200 \ \mu\text{A Except for MCLK OUT.}^{12} \ V_{\text{DD}} = 5 \ V. \\ I_{\text{SOURCE}} &= 100 \ \mu\text{A Except for MCLK OUT.}^{12} \ V_{\text{DD}} = 3 \ V. \end{split}$
SYSTEM CALIBRATION Positive Full-Scale Calibration Limit ¹⁴ Negative Full-Scale Calibration Limit ¹⁴ Offset Calibration Limit ¹⁴ Input Span ¹⁵	(1.05 × V _{REF})/GAIN -(1.05 × V _{REF})/GAIN -(1.05 × V _{REF})/GAIN (0.8 × V _{REF})/GAIN (2.1 × V _{REF})/GAIN	V max V max V max V min V min V max	GAIN Is the Selected PGA Gain (1 to 128) GAIN Is the Selected PGA Gain (1 to 128)
POWER REQUIREMENTS V _{DD} Voltage Power Supply Currents ¹⁶	+2.7 to +3.3	V min to V max	For Specified Performance Digital $1/Ps = 0$ V or V_{DD} . External MCLK IN and
V _{DD} Voltage Power Supply Currents ¹⁶	0.32 0.6 0.4 0.6 0.7 1.1 +4.75 to +5.25	mA max mA max mA max mA max mA max W min to V max	$\begin{array}{l} \text{CLK DIS = 1} \\ \text{BUF Bit = 0.} \ f_{\text{CLKIN}} = 1 \ \text{MHz. Gains of 1 to 128} \\ \text{BUF Bit = 0.} \ f_{\text{CLKIN}} = 1 \ \text{MHz. Gains of 1 to 128} \\ \text{BUF Bit = 0.} \ f_{\text{CLKIN}} = 2.4576 \ \text{MHz. Gains of 1 to 4} \\ \text{BUF Bit = 0.} \ f_{\text{CLKIN}} = 2.4576 \ \text{MHz. Gains of 8 to 128} \\ \text{BUF Bit = 1.} \ f_{\text{CLKIN}} = 2.4576 \ \text{MHz. Gains of 1 to 4} \\ \text{BUF Bit = 1.} \ f_{\text{CLKIN}} = 2.4576 \ \text{MHz. Gains of 1 to 4} \\ \text{BUF Bit = 1.} \ f_{\text{CLKIN}} = 2.4576 \ \text{MHz. Gains of 8 to 128} \\ \text{For Specified Performance} \\ \text{Digital I/Ps = 0 V or V_{DD}. External MCLK IN and CLK DIS = 1. \end{array}$
Standby (Power-Down) Current ¹⁷	0.45 0.7 0.6 0.85 0.9 1.3 16 8	mA max mA max mA max mA max mA max μA max μA max	$\begin{array}{l} BUF Bit = 0, f_{CLKIN} = 1 \ MHz. \ Gains of 1 \ to \ 128 \\ BUF Bit = 1, f_{CLKIN} = 1 \ MHz. \ Gains of 1 \ to \ 128 \\ BUF Bit = 0, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 0, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 1, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 1, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 1, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 1, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 1, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 1, f_{CLKIN} = 2.4576 \ MHz. \ Gains of 1 \ to \ 4 \\ BUF Bit = 1, f_{CLKIN} = 0 \ V \ or \ V_{DD}. \ V_{DD} = 5 \ V. \ See \ Figure \ 9 \\ External \ MCLK \ IN = 0 \ V \ or \ V_{DD}. \ V_{DD} = 3 \ V \\ \end{array}$
Power Supply Rejection ¹⁸	See Note 19	dB typ	

NOTES

Temperature range as follows: B Version, -40°C to +85°C.

²These numbers are established from characterization or design at initial product release.

³A calibration is effectively a conversion so these errors will be of the order of the conversion noise shown in Tables I and III. This applies after calibration at the temperature of interest.

⁴Recalibration at any temperature will remove these drift errors.

⁵Positive Full-Scale Error includes Zero-Scale Errors (Unipolar Offset Error or Bipolar Zero Error) and applies to both unipolar and bipolar input ranges.

⁶Full-Scale Drift includes Zero-Scale Drift (Unipolar Offset Drift or Bipolar Zero Drift) and applies to both unipolar and bipolar input ranges.

⁷Gain Error does not include Zero-Scale Errors. It is calculated as Full-Scale Error–Unipolar Offset Error for unipolar ranges and Full-Scale Error–Bipolar Zero Error for bipolar ranges

⁸Gain Error Drift does not include Unipolar Offset Drift/Bipolar Zero Drift. It is effectively the drift of the part if zero scale calibrations only were performed. ⁹This common-mode voltage range is allowed provided that the input voltage on analog inputs does not go more positive than V_{DD} + 30 mV or go more negative than

GND - 30 mV. Parts are functional with voltages down to GND - 200 mV, but with increased leakage at high temperature. 10 The analog input voltage range on AIN(+) is given here with respect to the voltage on AIN(-) on the HT7705 and is given with respect to the COMMON input on the

HT7706. The absolute voltage on the analog inputs should not go more positive than V_{DD} + 30 mV, or go more negative than GND – 30 mV for specified performance, input voltages of GND – 200 mV can be accommodated, but with increased leakage at high temperature.

 $^{11}V_{REF} = REF IN(+) - REF IN(-).$

¹²EThese logic output levels apply to the MCLK OUT only when it is loaded with one CMOS load. ¹³Sample tested at +25°C to ensure compliance.

¹⁴After calibration, if the analog input exceeds positive full scale, the converter will output all 1s. If the analog input is less than negative full scale, the device will output all 0s. ¹⁵These calibration and span limits apply provided the absolute voltage on the analog inputs does not exceed V_{DD} + 30 mV or go more negative than GND – 30 mV. The offset

calibration limit applies to both the unipolar zero point and the bipolar zero point. ¹⁶When using a crystal or ceramic resonator across the MCLK pins as the clock source for the device, the V_{DD} current and power dissipation will vary depending on the crystal or resonator type (see Clocking and Oscillator Circuit section).

¹⁷If the external master clock continues to run in standby mode, the standby current increases to 150 µA typical at 5 V and 75 µA at 3 V. When using a crystal or ceramic resonator across the MCLK pins as the clock source for the device, the internal oscillator continues to run in standby mode and the power dissipation depends on the crystal or resonator type (see Standby Mode section).

¹⁸Measured at dc and applies in the selected passband. PSRR at 50 Hz will exceed 120 dB with filter notches of 25 Hz or 50 Hz. PSRR at 60 Hz will exceed 120 dB with filter notches of 20 Hz or 60 Hz.

 $^{19}\mbox{PSRR}$ depends on both gain and $\,V_{\mbox{DD}}$

Gain	1	2	4	8-128
$V_{DD} = 3 V$	86	78	85	93
$V_{DD} = 5 V$	90	78	84	91

Specifications subject to change without notice.



Parameter	Limit at T _{MIN} , T _{MAX} (B Version)	Units	Conditions/Comments
f _{clkin} ^{3, 4}	400	kHz min	Master Clock Frequency: Crystal Oscillator or Externally Supplied
	2.5	MHz max	for Specified Performance
t _{clkin lo}	$0.4 imes t_{ m CLKIN}$	ns min	Master Clock Input Low Time. t _{CLKIN} = 1/f _{CLKIN}
t _{clkin hi}	$0.4 \times t_{\text{CLKIN}}$	ns min	Master Clock Input High Time
t ₁	$500 \times t_{CLKIN}$	ns nom	DRDY High Time
t ₂	100	ns min	RESET Pulsewidth
Read Operation			
t ₃	0	ns min	DRDY to CS Setup Time
t_4	120	ns min	CS Falling Edge to SCLK Rising Edge Setup Time
t ₅ 5	0	ns min	SCLK Falling Edge to Data Valid Delay
	80	ns max	$V_{DD} = +5 V$
	100	ns max	$V_{DD} = +3.0 \text{ V}$
t ₆	100	ns min	SCLK High Pulsewidth
t ₇	100	ns min	SCLK Low Pulsewidth
t ₇ t ₈	0	ns min	CS Rising Edge to SCLK Rising Edge Hold Time
t ₉ 6	10	ns min	Bus Relinquish Time after SCLK Rising Edge
	60	ns max	$V_{DD} = +5 V$
	100	ns max	$V_{DD} = +3.0 V$
t ₁₀	100	ns max	SCLK Falling Edge to <i>DRDY</i> High ⁷
Write Operation			
t ₁₁	120	ns min	CS Falling Edge to SCLK Rising Edge Setup Time
t ₁₂	30	ns min	Data Valid to SCLK Rising Edge Setup Time
t ₁₃	20	ns min	Data Valid to SCLK Rising Edge Hold Time
t ₁₄	100	ns min	SCLK High Pulsewidth
t ₁₅	100	ns min	SCLK Low Pulsewidth
t ₁₆	0	ns min	CS Rising Edge to SCLK Rising Edge Hold Time
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¹Sample tested at +25°C to ensure compliance. All input signals are specified with tr = tf = 5 ns (10% to 90% of V_{DD}) and timed from a voltage level of 1.6 V. ²See Figures 16 and 17.

³f_{CLKIN} Duty Cycle range is 45% to 55%. f_{CLKIN} must be supplied whenever the HT7705/HT7706 is not in Standby mode. If no clock is present in this case, the device can draw higher current than specified and possibly become uncalibrated.

⁴The HT7705/HT7706 is production tested with f_{CLKIN} at 2.4576 MHz (1 MHz for some I_{DD} tests). It is guaranteed by characterization to operate at 400 kHz. ⁵These numbers are measured with the load circuit of Figure 1 and defined as the time required for the output to cross the V_{0L} or V_{0H} limits. ⁶These numbers are derived from the measured time taken by the data output to change 0.5 V when loaded with the circuit of Figure 1. The measured number is then extrapolated back to remove effects of charging or discharging the 50 pF capacitor. This means that the times quoted in the timing characteristics are the two how compared for the data of the fortunal head head in the loading the start of the fortunal the timing characteristics are the true bus relinquish times of the part and as such are independent of external bus loading capacitances.

⁷DRDY returns high after the first read from the device after an output update. The same data can be read again, if required, while DRDY is high, although care should be taken that subsequent reads do not occur close to the next output update.

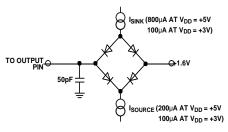


Figure 1. Load Circuit for Access Time and Bus Relinquish Time



ABSOLUTE MAXIMUM RATINGS*

(T_A = +25°C unless otherwise noted)

$\begin{array}{cccc} V_{DD} \ to \ GND & \dots & -0.3 \ V \ to \ +7 \ V \\ Analog \ Input \ Voltage \ to \ GND & \dots & -0.3 \ V \ to \ V_{DD} + \ 0.3 \ V \\ Reference \ Input \ Voltage \ to \ GND & \dots & -0.3 \ V \ to \ V_{DD} + \ 0.3 \ V \\ Digital \ Input \ Voltage \ to \ GND & \dots & -0.3 \ V \ to \ V_{DD} + \ 0.3 \ V \\ \end{array}$
Digital Miput Voltage to GND \dots -0.3 V to V _{DD} +0.3 V Operating Temperature Range
Commercial (B Version)40°C to +85°C Storage Temperature Range65°C to +150°C
Junction Temperature+150°C Plastic DIP Package, Power Dissipation450 mW θ_{JA} Thermal Impedance
Lead Temperature, (Soldering, 10 sec)+260°C

$\begin{array}{l} SOIC \mbox{ Package, Power Dissipation} \dots 450 \mbox{ mW} \\ \theta_{JA} \mbox{ Thermal Impedance} \dots 75^{\circ} \mbox{ C/W} \\ \mbox{ Lead Temperature, Soldering} \end{array}$
Vapor Phase (60 sec)+215°C
Infrared (15 sec)+220°C
SSOP Package, Power Dissipation
θ _{JA} Thermal Impedance 139°C/W
Lead Temperature, Soldering
Vapor Phase (60 sec)+215°C
Infrared (15 sec)+220°C
ESD Rating>4000 V

*Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Model	V _{DD} Supply	Temperature Range	Package Description
HT7705ANZ HT7705ARWZ HT7705ARTZ HT7705ARZ	2.7 V to 5.25 V 2.7 V to 5.25 V 2.7 V to 5.25 V 2.7 V to 5.25 V 2.7 V to 5.25 V	-40°C to +85°C -40°C to +85°C -40°C to +85°C -40°C to +85°C	Plastic DIP SOIC TSSOP SOP
HT7706ANZ HT7706ARWZ HT7706ARTZ HT7706ARZ	2.7 V to 5.25 V 2.7 V to 5.25 V 2.7 V to 5.25 V 2.7 V to 5.25 V 2.7 V to 5.25 V	-40°C to +85°C -40°C to +85°C -40°C to +85°C -40°C to +85°C	Plastic DIP SOIC TSSOP SOP

ORDERING GUIDE



PIN CONFIGURATIONS



PIN FUNCTION DESCRIPTIONS

Pin No.	Mnemonic	Function
1	SCLK	Serial Clock. Schmitt-Triggered Logic Input. An external serial clock is applied to this input to access serial data from the HT7705/HT7706. This serial clock can be a continuous clock with all data transmitted in a continuous train of pulses. Alternatively, it can be a noncontinuous clock with the information being transmitted to the HT7705/HT7706 in smaller batches of data.
2	MCLK IN	Master Clock signal for the device. This can be provided in the form of a crystal/resonator or external clock. A crystal/resonator can be tied across the MCLK IN and MCLK OUT pins. Alternatively, the MCLK IN pin can be driven with a CMOS-compatible clock and MCLK OUT left unconnected. The part can be operated with clock frequencies in the range 500 kHz to 5 MHz.
3	MCLK OUT	When the master clock for the device is a crystal/resonator, the crystal/resonator is connected between MCLK IN and MCLK OUT. If an external clock is applied to MCLK IN, MCLK OUT provides an inverted clock signal. This clock can be used to provide a clock source for external circuitry and is capable of driving one CMOS load. If the user does not require it, this MCLK OUT can be turned off via the CLK DIS bit of the Clock Register. This ensures that the part is not burning unnecessary power driving capacitive loads on MCLK OUT.
4	CS	Chip Select. Active low Logic Input used to select the HT7705/HT7706. With this input hard-wired low, the HT7705/HT7706 can operate in its three-wire interface mode with SCLK, DIN and DOUT used to interface to the device. <i>CS</i> can be used to select the device in systems with more than one device on the serial bus or as a frame synchronization signal in communicating with the HT7705/HT7706.
5	RESET	Logic Input. Active low input that resets the control logic, interface logic, calibration coefficients, digital filter and analog modulator of the part to power-on status.
6	AIN2(+)[AIN1]	HT7705: Positive input of the differential Analog Input Channel 2. HT7706: Analog Input Channel 1.
7	AIN1(+)[AIN2]	HT7705: Positive input of the differential Analog Input Channel 1. HT7706: Analog Input Channel 2.
8	AIN1(-)[COMMON]	HT7705: Negative input of the differential Analog Input Channel 1. HT7706: COMMON Input. Analog inputs for Channels 1, 2 and 3 are referenced to this input.
9	REF IN(+)	Reference Input. Positive input of the differential Reference Input to the HT7705/HT7706. The reference input is differential with the provision that REF IN(+) must be greater than REF IN(-). REF IN(+) can lie anywhere between V_{DD} and GND.



Pin No.	Mnemonic	Function
10	REF IN(-)	Reference Input. Negative input of the differential reference input to the HT7705/HT7706. The REF IN(-) can lie anywhere between V_{DD} and GND provided REF IN(+) is greater than REF IN(-).
11	AIN2(-)[AIN3]	HT7705: Negative input of the differential analog Input Channel 2. HT7706: Analog Input Channel 3.
12	DRDY	Logic Output. A logic low on this output indicates that a new output word is available from the HT7705/HT7706 data register. The <i>DRDY</i> pin will return high upon completion of a read operation of a full output word. If no data read has taken place between output updates, the <i>DRDY</i> line will return high for $500 \times t_{CLK N}$ cycles prior to the next output update. While <i>DRDY</i> is high, a read operation should neither be attempted nor in progress to avoid reading from the data register as it is being updated. The <i>DRDY</i> line will return low again when the update has taken place. <i>DRDY</i> is also used to indicate when the HT7705/HT7706 has completed its on-chip calibration sequence.
13	DOUT	Serial Data Output with serial data being read from the output shift register on the part. This output shift register can contain information from the setup register, communications register, clock register or data register, depending on the register selection bits of the Communications Register.
14	DIN	Serial Data Input with serial data being written to the input shift register on the part. Data from this input shift register is transferred to the setup register, clock register or communications register, depending, on the register selection bits of the Communications Register.
15	V _{DD}	Supply Voltage, +2.7 V to +5.25 V operation.
16	GND	Ground reference point for the HT7705/HT7706's internal circuitry.

OUTPUT NOISE (5 V OPERATION)

Table I shows the HT7705/HT7706 output rms noise for the selectable notch and -3 dB frequencies for the part, as selected by FS0 and FS1 of the Clock Register. The numbers given are for the bipolar input ranges with a V_{REF} of +2.5 V and V_{DD} = 5 V. These numbers are typical and are generated at an analog input voltage of 0 V with the part used in either buffered or unbuffered mode. Table II meanwhile shows the output *peak-to-peak* noise for the selectable notch and -3 dB frequencies for the part. *It is important to note that these numbers represent the resolution for which there will be no code flicker. They are not calculated based on rms noise but on peak-to-peak noise.* The numbers given are for bipolar input ranges with a V_{REF} of +2.5 V and for either buffered or unbuffered mode. These numbers are typical and are rounded to the nearest LSB. The numbers apply for the CLK DIV bit of the Clock Register set to 0.

Filter First		Typical Output RMS Noise in μ V							
Notch and O/P Data Rate	–3 dB Frequency	Gain of 1	Gain of 2	Gain of 4	Gain of 8	Gain of 16	Gain of 32	Gain of 64	Gain of 128
MCLK IN = 2.4	576 MHz								
50 Hz	13.1 Hz	4.1	2.1	1.2	0.75	0.7	0.66	0.63	0.6
60 Hz	15.72 Hz	5.1	2.5	1.4	0.8	0.75	0.7	0.67	0.62
250 Hz	65.5 Hz	110	49	31	17	8	3.6	2.3	1.7
500 Hz	131 Hz	550	285	145	70	41	22	9.1	4.7
MCLK IN = 1 M	1Hz								
20 Hz	5.24 Hz	4.1	2.1	1.2	0.75	0.7	0.66	0.63	0.6
25 Hz	6.55 Hz	5.1	2.5	1.4	0.8	0.75	0.7	0.67	0.62
100 Hz	26.2 Hz	110	49	31	17	8	3.6	2.3	1.7
200 Hz	52.4 Hz	550	285	145	70	41	22	9.1	4.7

Table I. Output RMS Noise vs. Gain and Output Update Rate @ 5 V



Filter First		Typical Peak-to-Peak Resolution Bits							
Notch and O/P Data Rate	–3 dB Frequency	Gain of 1	Gain of 2	Gain of 4	Gain of 8	Gain of 16	Gain of 32	Gain of 64	Gain of 128
MCLK IN = 2.4	576 MHz								
50 Hz	13.1 Hz	16	16	16	16	16	16	15	14
60 Hz	15.72 Hz	16	16	16	16	15	14	14	13
250 Hz	65.5 Hz	13	13	13	13	13	13	12	12
500 Hz	131 Hz	10	10	10	10	10	10	10	10
MCLK IN = 1 M	4Hz								
20 Hz	5.24 Hz	16	16	16	16	16	16	15	14
25 Hz	6.55 Hz	16	16	16	16	15	14	14	13
100 Hz	26.2 Hz	13	13	13	13	13	13	12	12
200 Hz	52.4 Hz	10	10	10	10	10	10	10	10

OUTPUT NOISE (3 V OPERATION)

Table III shows the HT7705/HT7706 output rms noise for the selectable notch and -3 dB frequencies for the part, as selected by FS0 and FS1 of the Clock Register. The numbers given are for the bipolar input ranges with a V_{REF} of +1.225 V and a V_{DD} = 3 V. These numbers are typical and are generated at an analog input voltage of 0 V with the part used in either buffered or unbuffered mode. Table II meanwhile shows the output *peak-to-peak* noise for the selectable notch and -3 dB frequencies for the part. It is important to note that these numbers represent the resolution for which there will be no code flicker. They are not calculated based on rms noise but on *peak-to-peak* noise. The numbers given are for bipolar input ranges with a V_{REF} of +1.225 V and for either buffered or unbuffered mode. These numbers are typical and are rounded to the nearest LSB. The numbers apply for the CLK DIV bit of the Clock Register set to 0.

Table III. Output RMS Noise vs. Gain and Output Upd	date Rate @ 3 V
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Filter First				Typical O	utput RMS N	oise in µV			
Notch and O/F	-3 dB	Gain of	Gain of	Gain of	Gain of	Gain of	Gain of	Gain of	Gain of
Data Rate	Frequency	1	2	4	8	16	32	64	128
MCLK IN = 2.4	576 MHz								
50 Hz	13.1 Hz	3.8	2.4	1.5	1.3	1.1	1.0	0.9	0.9
60 Hz	15.72 Hz	5.1	2.9	1.7	1.5	1.2	1.0	0.9	0.9
250 Hz	65.5 Hz	50	25	14	9.9	5.1	2.6	2.3	2.0
500 Hz	131 Hz	270	135	65	41	22	9.7	5.1	3.3
MCLK IN = 1	MHz								
20 Hz	5.24 Hz	3.8	2.4	1.5	1.3	1.1	1.0	0.9	0.9
25 Hz	6.55 Hz	5.1	2.9	1.7	1.5	1.2	1.0	0.9	0.9
100 Hz	26.2 Hz	50	25	14	9.9	5.1	2.6	2.3	2.0
200 Hz	52.4 Hz	270	135	65	41	22	9.7	5.1	3.3

Filter First			Typical Peak-to-Peak Resolution in Bits							
Notch and O/H Data Rate	P -3 dB Frequency	Gain of 1	Gain of 2	Gain of 4	Gain of 8	Gain of 16	Gain of 32	Gain of 64	Gain of 128	
MCLK IN = 2.4	4576 MHz									
50 Hz	13.1 Hz	16	16	15	15	14	13	13	12	
60 Hz	15.72 Hz	16	16	15	14	14	13	13	12	
250 Hz	65.5 Hz	13	13	13	13	12	12	11	11	
500 Hz	131 Hz	10	10	10	10	10	10	10	10	
MCLK IN = 1	MHz									
20 Hz	5.24 Hz	16	16	15	15	14	13	13	12	
25 Hz	6.55 Hz	16	16	15	14	14	13	13	12	
100 Hz	26.2 Hz	13	13	13	13	12	12	11	11	
200 Hz	52.4 Hz	10	10	10	10	10	10	10	10	

Table IV. Peak-to-Peak Resolution vs. Gain and Output Update Rate @ 3 V



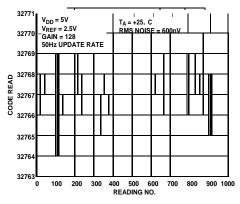


Figure 2. Typical Noise Plot @ Gain = 128 with 50 Hz Update Rate

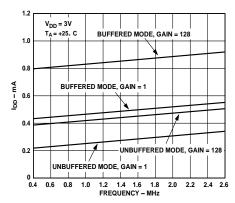


Figure 3. Typical IDD vs. MCLKIN Frequency @3 V

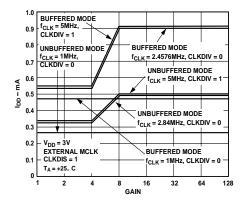


Figure 4. Typical I_{DD} vs. Gain and Clock Frequency @ 3 V

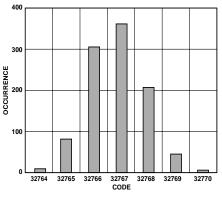


Figure 5. Histogram of Data in Figure 2

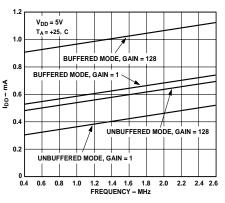


Figure 6. Typical IDD vs. MCLKIN Frequency @ 5 V

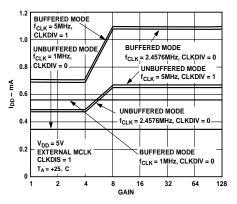


Figure 7. Typical I_{DD} vs. Gain and Clock Frequency @ 5 V



TEK STOP: SINGLE SEQ 50.0kS/s

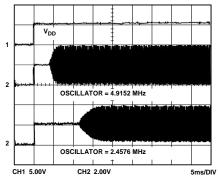


Figure 8. Typical Crystal Oscillator Power-Up Time

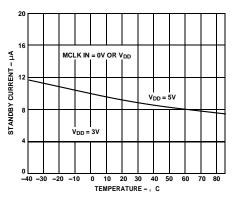


Figure 9. Standby Current vs. Temperature

ON-CHIP REGISTERS

The HT7705/HT7706 contains eight on-chip registers which can be accessed via the serial port of the part. The first of these is a Communications Register that controls the channel selection, decides whether the next operation is a read or write operation and also decides which register the next read or write operation accesses. All communications to the part must start with a write operation to the Communications Register. After power-on or *RESET*, the device expects a write to its Communications Register. The data written to this register determines whether the next operation to the part is a read or a write operation and also determines to which register this read or write operation occurs. Therefore, write access to any of the other registers on the part starts with a write operation to the Communications Register followed by a write to the selected register. A read operation from any other register on the part (including the Communications Register itself and the output data register) starts with a write operation to the Communications Register is also available by reading from the Communications Register. The second register is a Setup Register that determines calibration mode, gain setting, bipolar/unipolar operation and buffered mode. The third register is labelled the Clock Register and contains the filter selection bits and clock control bits. The fourth register is the Data Register from which the output data from the part is accessed. The final registers are the calibration registers which store channel calibration data. The registers are discussed in more detail in the following sections.

Communications Register (RS2, RS1, RS0 = 0, 0, 0)

The Communications Register is an 8-bit register from which data can either be read or to which data can be written. All communications to the part must start with a write operation to the Communications Register. The data written to the Communications Register determines whether the next operation is a read or write operation and to which register this operation takes place. Once the subsequent read or write operation to the selected register is complete, the interface returns to where it expects a write operation to the Communications Register. This is the default state of the interface, and on power-up or after a *RESET*, the HT7705/HT7706 is in this default state waiting for a write operation to the Communications Register. In situations where the interface sequence is lost, if a write operation of sufficient duration (containing at least 32 serial clock cycles) takes place with DIN high, the HT7705 returns to this default state. Table V outlines the bit designations for the Communications Register.

Table V. Communications Register

0/DRDY (0)	RS2 (0)	RS1 (0)	RS0 (0)	R/W (0)	STBY (0)	CH1 (0)	СНО (0)
0/DRDY	For a write operation, a "0" must be written to this bit so that the write operation to the Communications Registe actually takes place. If a "1" is written to this bit, the part will not clock on to subsequent bits in the register. It will stay at this bit location until a "0" is written to this bit. Once a "0" is written to this bit, the next seven bits will be loaded to the Communications Register. For a read operation, this bit provides the status of the <i>DRDY</i> fla from the part. The status of this bit is the same as the <i>DRDY</i> output pin.						
RS2-RS0	tion takes place lected register	ce, as shown in T is complete, th	Table VI, along w e part returns to	vith the register s	size. When the re ing for a write of	ead or write oper peration to the C	d or write opera- ration to the se- communications



Table VI. Register Selection

RS2	RS1	RS0	Register	Register Size
0	0	0	Communications Register	8 Bits
0	0	1	Setup Register	8 Bits
0	1	0	Clock Register	8 Bits
0	1	1	Data Register	16 Bits
1	0	0	Test Register	8 Bits
1	0	1	No Operation	
1	1	0	Offset Register	24 Bits
1	1	1	Gain Register	24 Bits

R/W Read/Write Select. This bit selects whether the next operation is a read or write operation to the selected register. A "0" indicates a write cycle for the next operation to the appropriate register, while a "1" indicates a read operation from the appropriate register.

STBYStandby. Writing a "1" to this bit puts the part into its standby or power-down mode. In this mode, the part con-
sumes only 10 μA of power supply current. The part retains its calibration coefficients and control word informa-
tion when in STANDBY. Writing a "0" to this bit places the part in its normal operating mode.

CH1-CH0 Channel Select. These two bits select a channel for conversion or for access to the calibration coefficients as outlined in Table VII. Three pairs of calibration registers on the part are used to store the calibration coefficients following a calibration on a channel. They are shown in Tables VII for the HT7705 and Table VIII for the HT7706 to indicate which channel combinations have independent calibration coefficients. With CH1 at Logic 1 and CH0 at a Logic 0, the part looks at the AIN1(-) input internally shorted to itself on the HT7705 or at COMMON internally shorted to itself on the HT7706. This can be used as a test method to evaluate the noise performance of the part with no external noise sources. In this mode, the AIN1(-)/COMMON input should be connected to an external voltage within the allowable common-mode range for the part.

Table VII. Channel Selection for HT7705

CH1	CH0	AIN(+)	AIN(-)	Calibration Register Pair
0	0	AIN1(+)	AIN1(-)	Register Pair 0
0	1	AIN2(+)	AIN2(-)	Register Pair 1
1	0	AIN1(-)	AIN1(-)	Register Pair 0
1	1	AIN1(-)	AIN2(-)	Register Pair 2

CH1	CH0	AIN	Reference	Calibration Register Pair
0	0	AIN1	COMMON	Register Pair 0
0	1	AIN2	COMMON	Register Pair 1
1	0	COMMON	COMMON	Register Pair 0
1	1	AIN3	COMMON	Register Pair 2

Table VIII. Channel Selection for HT7706



Setup Register (RS2, RS1, RS0 = 0, 0, 1); Power On/Reset Status: 01 Hex

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The Setup Register is an eight bit register from which data can either be read or to which data can be written. Table IX outlines the bit designations for the Setup Register.

Table IX. Setup Register

_								
	MD1 (0)	MD0 (0)	G2 (0)	G1 (0)	G0 (0)	B/U (0)	BUF (0)	FSYNC (1)

MD1	MD0	Operating Mode
0	0	Normal Mode: this is the normal mode of operation of the device whereby the device is performing normal conversions.
0	1	Self-Calibration: this activates self-calibration on the channel selected by CH1 and CH0 of the Communications Register. This is a one-step calibration sequence and when complete the part returns to Normal Mode with MD1 and MD0 returning to 0, 0. The <i>DRDY</i> output or bit goes high when calibration is initiated and returns low when this self-calibration is complete and a new valid word is available in the data register. The zero-scale calibration is performed at the selected gain on internally shorted (zeroed) inputs and the full-scale calibration is performed at the selected gain on an internally-generated V _{REF} /Selected Gain.
1	0	Zero-Scale System Calibration: this activates zero scale system calibration on the channel selected by CH1 and CH0 of the Communications Register. Calibration is performed at the selected gain on the input voltage provided at the analog input during this calibration sequence. This input voltage should remain stable for the duration of the calibration. The <i>DRDY</i> output or bit goes high when calibration is initiated and returns low when this zero-scale calibration is complete and a new valid word is available in the data register. At the end of the calibration, the part returns to Normal Mode with MD1 and MD0 returning to 0, 0.
1	1	Full-Scale System Calibration: this activates full-scale system calibration on the selected input channel. Calibration is performed at the selected gain on the input voltage provided at the analog input during this calibration sequence. This input voltage should remain stable for the duration of the calibration. Once again, the <i>DRDY</i> output or bit goes high when calibration is initiated and returns low when this full-scale calibration is complete and a new valid word is available in the data register. At the end of the calibration, the part returns to Normal Mode with MD1 and MD0 returning to 0, 0.

G2-G0

Gain Selection Bits. These bits select the gain setting for the on-chip PGA as outlined in Table X.

Table X. Gain Selection

G2	G1	GO	Gain Setting
0	0	0	1
0	0	1	2
0	1	0	4
0	1	1	8
1	0	0	16
1	0	1	32
1	1	0	32 64
1	1	1	128

B/U Bipolar/Unipolar Operation. A "0" in this bit selects Bipolar Operation. A "1" in this bit selects Unipolar Operation.

 $BUF Buffer Control. With this bit at "0," the on-chip buffer on the analog input is shorted out. With the buffer shorted out, the current flowing in the V_{DD} line is reduced. When this bit is high, the on-chip buffer is in series with the analog input allowing the input to handle higher source impedances.$

FSYNCFilter Synchronization. When this bit is high, the nodes of the digital filter, the filter control logic and the calibra-
tion control logic are held in a reset state and the analog modulator is also held in its reset state. When this bit
goes low, the modulator and filter start to process data and a valid word is available in $3 \times 1/($ output update rate),
i.e., the settling time of the filter. This FSYNC bit does not affect the digital interface and does not reset the
DRDY output if it is low.



Clock Register (RS2, RS1, RS0 = 0, 1, 0); Power-On/Reset Status: 05 Hex

The Clock Register is an 8-bit register from which data can either be read or to which data can be written. Table XI outlines the bit designations for the Clock Register.

Table XI. Clock Register

ZERO (0)	ZERO (0)	ZERO (0)	CLKDIS (0)	CLKDIV (0)	CLK (1)	FS1 (0)	FS0 (1)			
ZERO		Zero. A zero MUST be written to these bits to ensure correct operation of the HT7705/HT7706. Failure to do so may result in unspecified operation of the device.								
CLKDIS	Master Clock Disable Bit. A Logic 1 in this bit disables the master clock from appearing at the MCLK OUT pin. When disabled, the MCLK OUT pin is forced low. This feature allows the user the flexibility of using the MCLK OUT as a clock source for other devices in the system or of turning off the MCLK OUT as a power saving feature. When using an external master clock on the MCLK IN pin, the HT7705/HT7706 continues to have internal clocks and will convert normally with the CLKDIS bit active. When using a crystal oscillator or ceramic resonator across the MCLK IN and MCLK OUT pins, the HT7705/HT7706 clock is stopped and no conversions take place when the CLKDIS bit is active.									
CLKDIV	before being u with a 4.9152 specified 2.45	Clock Divider Bit. With this bit at a Logic 1, the clock frequency appearing at the MCLK IN pin is divided by two before being used internally by the HT7705/HT7706. For example, when this bit is set to 1, the user can operate with a 4.9152 MHz crystal between MCLK IN and MCLK OUT and internally the part will operate with the specified 2.4576 MHz. With this bit at a Logic 0, the clock frequency appearing at the MCLK IN pin is the frequency used internally by the part.								
CLK	has a master c be set to a "1." this bit should also chooses (a	lock frequency If the device ha be set to a "0." T along with FS1 a	et in accordance w of 2.4576 MHz is a master clock 'his bit sets up th and FSO) the outp device, then the H	(CLKDIV = 0) or frequency of 1 M e appropriate sca out update rate fo	4.9152 MHz (CL 1Hz (CLKDIV = (aling currents fo or the device. If t	KDIV = 1), then)) or 2 MHz (CLH r a given operati his bit is not set	this bit should KDIV = 1), ng frequency and correctly for the			
FS1, FS0	-3 dB frequent association wi frequency, as w and gain on th time) for the d of the filter is s	cy as outlined in th the gain sele well as the selec e output noise a evice is equal to selected at 50 Ha	th the CLK bit, FS Table XII. The or ction, it also dete ted gain, impacts and effective reso the frequency se z, a new word is a ole every 2 ms. A cr	n-chip digital filt ermines the outp resolution. Tabl olution of the par elected for the first available at a 50 l	er provides a sin ut noise of the d es I to IV show th rt. The output d st notch of the fil Hz output rate o	c ³ (or Sinx/x ³) fi levice. Changing he effect of filter ata rate (or effec ter. For example r every 20 ms. If	lter response. In the filter notch notch frequency tive conversion , if the first notch the first notch is			
	filter first note 500 Hz, the set ing the step ing high, the settli	h at 50 Hz, the s tling time is 8 m out change to a re ng-time will be 3	o a full-scale step settling time of th is max. This settl eset of the digital 3 × 1/(output dat pined by the pro-	e filter to a full-s ing time can be re filter. In other wo ca rate) from whe	cale step input is educed to $3 \times 1/$ rds, if the step in en the FSYNC bit	s 80 ms max. If th (output data rate out takes place w returns low.	ne first notch is a e) by synchroniz- ith the FSYNC bit			

The -3 dB frequency is determined by the programmed first notch frequency according to the relationship:

filter –3 *dB frequency* = 0.262 × *filter first notch frequency*

Table XII. Output Update Rates

CLK*	FS1	FS0	Output Update Rate	-3 dB Filter Cutoff
0	0	0	20 Hz	5.24 Hz
0	0	1	25 Hz	6.55 Hz
0	1	0	100 Hz	26.2 Hz
0	1	1	200 Hz	52.4 Hz
1	0	0	50 Hz	13.1 Hz
1	0	1	60 Hz	15.7 Hz
1	1	0	250 Hz	65.5 Hz
1	1	1	500 Hz	131 Hz

*Assumes correct clock frequency on MCLK IN pin with CLKDIV bit set appropriately.



Data Register (RS2, RS1, RS0 = 0, 1, 1)

The Data Register on the part is a 16-bit read-only register that contains the most up-to-date conversion result from the HT7705/HT7706. If the Communications Register sets up the part for a write operation to this register, a write operation must actually take place to return the part to where it is expecting a write operation to the Communications Register. However, the 16 bits of data written to the part will be ignored by the HT7705/HT7706.

Test Register (RS2, RS1, RS0 = 1, 0, 0); Power-On/Reset Status: 00 Hex

The part contains a Test Register that is used when testing the device. The user is advised not to change the status of any of the bits in this register from the default (Power-on or RESET) status of all 0s as the part will be placed in one of its test modes and will not operate correctly.

Zero-Scale Calibration Register (RS2, RS1, RS0 = 1, 1, 0); Power-On/Reset Status: 1F4000 Hex

The HT7705/HT7706 contains independent sets of zero-scale registers, one for each of the input channels. Each of these registers is a 24-bit read/write register; 24 bits of data must be written otherwise no data will be transferred to the register. This register is used in conjunction with its associated full-scale register to form a register pair. These register pairs are associated with input channel pairs as outlined in Table VII. While the part is set up to allow access to these registers over the digital interface, the part itself no longer has access to the register coefficients to correctly scale the output data. As a result, there is a possibility that after accessing the calibration registers (either read or write operation) the first output data read from the part may contain incorrect data. In addition, a write to the calibration register should not be attempted while a calibration is in progress. These eventualities can be avoided by taking the FSYNC bit in the mode register high before the calibration register operation and taking it low after the operation is complete.

Full-Scale Calibration Register (RS2, RS1, RS0 = 1, 1, 1); Power-On/Reset Status: 5761AB Hex

The HT7705/HT7706 contains independent sets of full-scale registers, one for each of the input channels. Each of these registers is a 24-bit read/write register; 24 bits of data must be written otherwise no data will be transferred to the register. This register is used in conjunction with its associated zero-scale register to form a register pair. These register pairs are associated with input channel pairs as outlined in Table VII. While the part is set up to allow access to these registers over the digital interface, the part itself no longer has access to the register coefficients to correctly scale the output data. As a result, there is a possibility that after accessing the calibration registers (either read or write operation) the first output data read from the part may contain incorrect data. In addition, a write to the calibration register should not be attempted while a calibration is in progress. These eventualities can be avoided by taking FSYNC bit in the mode register high before the calibration register operation and taking it low after the operation is complete.

CALIBRATION SEQUENCES

The HT7705/HT7706 contains a number of calibration options as previously outlined. Table XIII summarizes the calibration types, the operations involved and the duration of the operations. There are two methods of determining the end of calibration. The first is to monitor when *DRDY* returns low at the end of the sequence. *DRDY* not only indicates when the sequence is complete, but also that the part has a valid new sample in its data register. This valid new sample is the result of a normal conversion which follows the calibration sequence. The second method of determining when calibration is complete is to monitor the MD1 and MD0 bits of the Setup Register. When these bits return to 0 (0 following a calibration command), it indicates that the calibration sequence is complete. This method does not give any indication of there being a valid new result in the data register. However, it gives an earlier indication than *DRDY* that calibration is complete. The duration to when the Mode Bits (MD1 and MD0) return to 0 (0 represents the duration of the calibration carried out). The sequence to when *DRDY* goes low also includes a normal conversion and a pipeline delay, t_P, to correctly scale the results of this first conversion. t_P will never exceed 2000 × t_{CLKIN}. The time for both methods is given in the table.

Calibration Type	MD1, MD0	Calibration Sequence	Duration to Mode Bits	Duration to DRDY	
Self-Calibration	0, 1	Internal ZS Cal @ Selected Gain + Internal FS Cal @ Selected Gain	6 × 1/Output Rate	$9 \times 1/\text{Output Rate} + t_P$	
ZS System Calibration FS System Calibration	1, 0 1, 1	ZS Cal on AIN @ Selected Gain FS Cal on AIN @ Selected Gain	$3 \times 1/0$ utput Rate $3 \times 1/0$ utput Rate	$\begin{array}{l} 4\times 1/\text{Output Rate} + t_P \\ 4\times 1/\text{Output Rate} + t_P \end{array}$	

Table XIII. Calibration Sequences



CIRCUIT DESCRIPTION

The HT7705/HT7706 is a sigma-delta A/D converter with onchip digital filtering, intended for the measurement of wide dynamic range, low frequency signals such as those in industrial control or process control applications. It contains a sigma-delta (or charge-balancing) ADC, a calibration microcontroller with on-chip static RAM, a clock oscillator, a digital filter and a bidirectional serial communications port. The part consumes only 320 µA of power supply current, making it ideal for batterypowered or loop-powered instruments. These parts operate with a supply voltage of 2.7 V to 3.3 V or 4.75 V to 5.25 V.

The HT7705 contains two programmable-gain fully differential analog input channels, while the HT7706 contains three pseudo differential analog input channels. The selectable gains on these inputs are 1, 2, 4, 8, 16, 32, 64 and 128 allowing the part to accept unipolar signals of between 0 mV to +20 mV and 0 V to +2.5 V, or bipolar signals in the range from \pm 20 mV to \pm 2.5 V when the reference input voltage equals +2.5 V. With a reference voltage of +1.225 V, the input ranges are from 0 mV to +10 mV to 0 V to +1.225 V in unipolar mode, and from \pm 10 mV to \pm 1.225 V in bipolar mode. Note that the bipolar ranges are with respect to AIN(–) on the HT7705, and with respect to GND.

The input signal to the analog input is continuously sampled at a rate determined by the frequency of the master clock, MCLK IN, and the selected gain. A charge-balancing A/D converter (Sigma-Delta Modulator) converts the sampled signal into a digital pulse train whose duty cycle contains the digital information. The programmable gain function on the analog input is also incorporated in this sigma-delta modulator with the input sampling frequency being modified to give the higher gains. A sinc³ digital low-pass filter processes the output of the sigma-delta modulator and updates the output register at a rate determined by the first notch frequency of this filter. The output data can be read from the serial port randomly or periodically at any rate up to the output register update rate. The first notch of this digital filter (and hence its -3 dB frequency) can be programmed via the Setup Register bits FS0 and FS1. With a master clock frequency of 2.4576 MHz, the programmable range for this first notch frequency is from 50 Hz to 500 Hz, giving a programmable range for the -3 dB frequency of 13.1 Hz to 131 Hz. With a master clock frequency of 1 MHz, the programmable range for this first notch frequency is from 20 Hz to 200 Hz, giving a programmable range for the -3 dB frequency of 5.24 Hz to 52.4 Hz.

The basic connection diagram for the HT7705 is shown in Figure 10. This shows the HT7705 being driven from the analog +5 V supply. An AD780, precision +2.5 V reference, provides the reference source for the part. On the digital side, the part is configured for three-wire operation with *CS* tied to GND. A quartz crystal or ceramic resonator provide the master clock source for the part. In most cases, it will be necessary to connect capacitors on the crystal or resonator to ensure that it does not oscillate at overtones of its fundamental operating frequency. The values of capacitors will vary, depending on the manufacturer's specifications. The same setup applies to the HT7706.

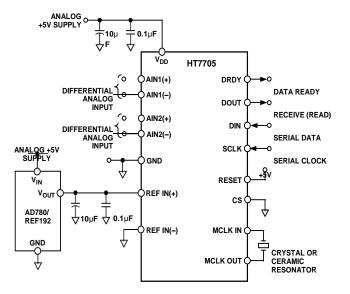


Figure 10. HT7705 Basic Connection Diagram



ANALOG INPUT

Analog Input Ranges

The HT7705 contains two differential analog input pairs AIN1(+), AIN1(-) and AIN2(+), AIN2(-). These input pairs provide programmable-gain, differential input channels that can handle either unipolar or bipolar input signals. It should be noted that the bipolar input signals are referenced to the respective AIN(-) input of each input pair. The HT7706 contains three pseudo differential analog input pairs AIN1, AIN2 and AIN3, which are referenced to the COMMON input on the part.

In unbuffered mode, the common-mode range of the input is from GND to V_{DD} , provided that the absolute value of the analog input voltage lies between GND – 30 mV and V_{DD} + 30 mV. This means that in unbuffered mode the part can handle both unipolar and bipolar input ranges for all gains. Absolute voltages of GND - 200 mV can be accommodated on the analog inputs at 25°C without degradation in performance, but leakage current increases appreciably with increasing temperature. In buffered mode, the analog inputs can handle much larger source impedances, but the absolute input voltage range is restricted to between GND + 50 mV to V_{DD} – 1.5 V which also places restrictions on the common-mode range. This means that in buffered mode there are some restrictions on the allowable gains for bipolar input ranges. Care must be taken in setting up the common-mode voltage and input voltage range so that the above limits are not exceeded, otherwise there will be a degradation in linearity performance.

In unbuffered mode, the analog inputs look directly into the 7 pF input sampling capacitor, C_{SAMP} . The dc input leakage current in this unbuffered mode is 1 nA maximum. As a result, the analog inputs see a dynamic load that is switched at the input sample rate (see Figure 11). This sample rate depends on master clock frequency and selected gain. C_{SAMP} is charged to AIN(+) and discharged to AIN(-) every input sample cycle. The effective on-resistance of the switch, R_{SW}, is typically 7 k Ω .

 C_{SAMP} must be charged through R_{SW} and through any external source impedances every input sample cycle. Therefore, in unbuffered mode, source impedances mean a longer charge time for C_{SAMP} and this may result in gain errors on the part. Table XIV shows the allowable external resistance/capacitance values, for unbuffered mode, such that no gain error to the 16-bit level is introduced on the part. Note that these capacitances are total capacitances on the analog input, external capacitance plus 10 pF capacitance from the pins and lead frame of the device.

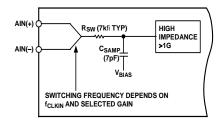


Figure 11. Unbuffered Analog Input Structure

Table XIV. External R, C Combination for No 16-Bit Gain	
Error (Unbuffered Mode Only)	

	External Capacitance (pF)					
Gain	0	50	100	500	1000	5000
1	368 kΩ	90.6 kΩ	54.2 kΩ	14.6 kΩ	8.2 kΩ	2.2 kΩ
2	177.2 kΩ	44.2 kΩ	26.4 kΩ	7.2 kΩ	$4 \mathrm{k}\Omega$	$1.12 \ \mathrm{k}\Omega$
4	82.8 kΩ	21.2 kΩ	12.6 kΩ	$3.4 \text{ k}\Omega$	1.94 kΩ	540Ω
8-128	$35.2 \text{ k}\Omega$	9.6 kΩ	$5.8 \mathrm{k}\Omega$	1.58Ω	880 Ω	240Ω

In buffered mode, the analog inputs look into the high-impedance inputs stage of the on-chip buffer amplifier. C_{SAMP} is charged via this buffer amplifier such that source impedances do not affect the charging of C_{SAMP} . This buffer amplifier has an offset leakage current of 1 nA. In this buffered mode, large source impedances result in a small dc offset voltage developed across the source impedance, but not in a gain error.

Input Sample Rate

The modulator sample frequency for the HT7705/HT7706 remains at f_{CLKIN}/128 (19.2 kHz @ f_{CLKIN} = 2.4576 MHz) regardless of the selected gain. However, gains greater than 1 are achieved by a combination of multiple input samples per modulator cycle and a scaling of the ratio of reference capacitor to input capacitor. As a result of the multiple sampling, the input sample rate of the device varies with the selected gain (see Table XV). In buffered mode, the input is buffered before the input sampling capacitor. In unbuffered mode, where the analog input looks directly into the sampling capacitor, the effective input impedance is $1/C_{SAMP} \times f_S$ where C_{SAMP} is the input sampling capacitance and f_S is the input sample rate.

Table XV. Input Sampling Frequency vs. Gain

Gain	Input Sampling Frequency (fs)
1	f _{CLKIN} /64 (38.4 kHz @ f _{CLKIN} = 2.4576 MHz)
2	$2 \times f_{CLKIN}/64$ (76.8 kHz @ f_{CLKIN} = 2.4576 MHz)
4	$4 \times f_{CLKIN}/64$ (76.8 kHz @ f_{CLKIN} = 2.4576 MHz)
8-128	$8 \times f_{\text{CLKIN}}/64$ (307.2 kHz @ f_{CLKIN} = 2.4576 MHz)

Bipolar/Unipolar Inputs

The analog inputs on the HT7705/HT7706 can accept either unipolar or bipolar input voltage ranges. Bipolar input ranges do not imply that the part can handle negative voltages on its analog input, since the analog input cannot go more negative than -30 mV to ensure correct operation of these parts. The input channels are fully differential. As a result, on the HT7705, the voltage to which the unipolar and bipolar signals on the AIN(+) input are referenced is the voltage on the respective AIN(-) input. On the HT7706, the voltages applied to the analog input channels are referenced to the COMMON input. For example, if AIN1(-) is +2.5 V and the HT7705 is configured for unipolar operation with a gain of 2 and a V_{REF} of +2.5 V, the input voltage range on the AIN1(+) input is +2.5 V to +3.75 V. If AIN1(-) is +2.5 V and the HT7705 is configured for bipolar mode with a gain of 2 and a V_{REF} of +2.5 V, the analog input range on the AIN1(+) input is +1.25 V to +3.75 V (i.e., 2.5 V \pm 1.25 V). If AIN1(-) is at GND, the part cannot be configured for bipolar ranges in excess of \pm 30 mV.



Bipolar or unipolar options are chosen by programming the B/U bit of the Setup Register. This programs the channel for either unipolar or bipolar operation. Programming the channel for either unipolar or bipolar operation does not change any of the input signal conditioning, it simply changes the data output coding and the points on the transfer function where calibrations occur.

REFERENCE INPUT

The HT7705/HT7706's reference inputs, REF IN(+) and REF IN(-), provide a differential reference input capability. The common-mode range for these differential inputs is from GND to V_{DD}. The nominal reference voltage, V_{REF} (REF IN(+) – REF IN(-)), for specified operation, is +2.5 V for the HT7705/HT7706 operated with a V_{DD} of 5 V and +1.225 V for the HT7705/HT7706 operated with a V_{DD} of 3 V. The part is functional with V_{REF} voltages down to 1 V, but with degraded performance as the output noise will, in terms of LSB size, be larger. REF IN(+) must always be greater than REF IN(-) for correct operation of the HT7705/HT7706.

Both reference inputs provide a high impedance, dynamic load similar to the analog inputs in unbuffered mode. The maximum dc input leakage current is ± 1 nA over temperature, and source resistance may result in gain errors on the part. In this case, the sampling switch resistance is 5 k\Omega typ and the reference capacitor (C_{REF}) varies with gain. The sample rate on the reference inputs is $f_{\text{CLKIN}}/64$ and does not vary with gain. For gains of 1 and 2, C_{REF} is 8 pF; for a gain of 16, it is 5.5 pF, for a gain of 128, it is 3.3125 pF.

The output noise performance outlined in Tables I through IV is for an analog input of 0 V, which effectively removes the effect of noise on the reference. To obtain the same noise performance as shown in the noise tables over the full input range requires a low noise reference source for the HT7705/HT7706. If the reference noise in the bandwidth of interest is excessive, it will degrade the performance of the HT7705/HT7706. In applications where the excitation voltage for the bridge transducer onthe analog input also derives the reference voltage for the part, the effect of the noise in the excitation voltage will be removed as the application is ratiometric. Recommended reference voltage sources for the HT7705 with a V_{DD} of 5 V include the AD780, REF43 and REF192, while the recommended reference sources for the HT7705 operated with a V_{DD} of 3 V include the AD589 and AD1580. It is generally recommended to decouple the output of these references in order to further reduce the noise level.

DIGITAL FILTERING

The HT7705/HT7706 contains an on-chip low-pass digital filter which processes the output of the part's sigma-delta modulator. Therefore, the part not only provides the analog-to-digital conversion function but also provides a level of filtering. There are a number of system differences when the filtering function is provided in the digital domain rather than the analog domain and the user should be aware of these.

First, since digital filtering occurs after the A-to-D conversion process, it can remove noise injected during the conversion process. Analog filtering cannot do this. Also, the digital filter can be made programmable far more readily than an analog filter. Depending on the digital filter design, this gives the user the capability of programming cutoff frequency and output update rate.

On the other hand, analog filtering can remove noise superimposed on the analog signal before it reaches the ADC. Digital filtering cannot do this and noise peaks riding on signals near full scale have the potential to saturate the analog modulator and digital filter, even though the average value of the signal is within limits. To alleviate this problem, the HT7705/HT7706 has overrange headroom built into the sigma-delta modulator and digital filter, which allows overrange excursions of 5% above the analog input range. If noise signals are larger than this, consideration should be given to analog input filtering, or to reducing the input channel voltage so that its full-scale is half that of the analog input channel full-scale. This will provide an overrange capability greater than 100% at the expense of reducing the dynamic range by 1 bit (50%).

In addition, the digital filter does not provide any rejection at integer multiples of the digital filter's sample frequency. However, the input sampling on the part provides attenuation at multiples of the digital filter's sampling frequency so that the unattenuated bands actually occur around multiples of the sampling frequency fs (as defined in Table XV). Thus the unattenuated bands occur at n × fs (where n = 1, 2, 3 . . .). At these frequencies, there are frequency bands, $\pm f_{3\,dB}$ wide $f_{3\,dB}$ is the cutoff frequency of the digital filter) at either side where noise passes unattenuated to the output.

Filter Characteristics

The HT7705/HT7706's digital filter is a low-pass filter with a $(sinx/x)^3$ response (also called sinc³). The transfer function for this filter is described in the z-domain by:

$$H(z) = \frac{\left|\frac{1}{N} \times \frac{1 - Z^{-N}}{1 - Z^{-1}}\right|^{3}}{N}$$

and in the frequency domain by:

$$H(f) = \frac{1}{N} \times \frac{SIN(N \times \pi \times f/f_s)}{SIN(\pi \times f/f_s)}^{3}$$

where N is the ratio of the modulator rate to the output rate. Phase Response:

$$\angle H = -3 \pi (N-2) \times f/f_s Rad$$

Figure 4 shows the filter frequency response for a cutoff frequency of 15.72 Hz, which corresponds to a first filter notch frequency of 60 Hz. The plot is shown from dc to 390 Hz. This response is repeated at either side of the digital filter's sample frequency and at either side of multiples of the filter's sample frequency.

The response of the filter is similar to that of an averaging filter, but with a sharper roll-off. The output rate for the digital filter corresponds with the positioning of the first notch of the filter's frequency response. Thus, for the plot of Figure 12 where the output rate is 60 Hz, the first notch of the filter is at 60 Hz. The notches of this (sinx/x)³ filter are repeated at multiples of the first notch. The filter provides attenuation of better than 100 dB at these notches.



The cutoff frequency of the digital filter is determined by the value loaded to bits FS0 to FS1 in the CLOCK Register. Programming a different cutoff frequency via FS0 and FS1 does not alter the profile of the filter response, it changes the frequency of the notches. The output update of the part and the frequency of the first notch correspond.

Since the HT7705/HT7706 contains this on-chip, low-pass filtering, a settling time is associated with step function inputs and data on the output will be invalid after a step change until the settling time has elapsed. The settling time depends upon the output rate chosen for the filter. The settling time of the filter to a full-scale step input can be up to four times the output data period. For a synchronized step input (using the FSYNC function), the settling time is three times the output data period.

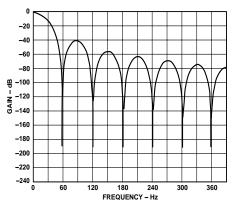


Figure 12. Frequency Response of HT7705 Filter

Post-Filtering

The on-chip modulator provides samples at a 19.2 kHz output rate with $f_{\rm CLKIN}$ at 2.4576 MHz. The on-chip digital filter decimates these samples to provide data at an output rate that corresponds to the programmed output rate of the filter. Since the output data rate is higher than the Nyquist criterion, the output rate for a given bandwidth will satisfy most application requirements. There may, however, be some applications which require a higher data rate for a given bandwidth and noise performance. Applications that need this higher data rate will require some post-filtering following the digital filter of the HT7705/HT7706.

For example, if the required bandwidth is 7.86 Hz, but the required update rate is 100 Hz, the data can be taken from the HT7705/HT7706 at the 100 Hz rate giving a -3 dB bandwidth of 26.2 Hz. Post-filtering can be applied to this to reduce the bandwidth and output noise, to the 7.86 Hz bandwidth level, while maintaining an output rate of 100 Hz.

Post-filtering can also be used to reduce the output noise from the device for bandwidths below 13.1 Hz. At a gain of 128 and a bandwidth of 13.1 Hz, the output rms noise is 450 nV. This is essentially device noise or white noise and since the input is chopped, the noise has a primarily flat frequency response. By reducing the bandwidth below 13.1 Hz, the noise in the resultant passband can be reduced. A reduction in bandwidth by a factor of 2 results in a reduction of approximately 1.25 in the output rms noise. This additional filtering will result in a longer settling-time.

ANALOG FILTERING

The digital filter does not provide any rejection at integer multiples of the modulator sample frequency, as outlined earlier. However, due to the HT7705/HT7706's high oversampling ratio, these bands occupy only a small fraction of the spectrum and most broadband noise is filtered. This means that the analog filtering requirements in front of the HT7705/HT7706 are considerably reduced versus a conventional converter with no on-chip filtering. In addition, because the part's common-mode rejection performance of 100 dB extends out to several kHz, common-mode noise in this frequency range will be substantially reduced.

Depending on the application, however, it may be necessary to provide attenuation prior to the HT7705/HT7706 in order to eliminate unwanted frequencies from these bands which the digital filter will pass. It may also be necessary in some applications to provide analog filtering in front of the HT7705/HT7706 to ensure that differential noise signals outside the band of interest do not saturate the analog modulator.

If passive components are placed in front of the HT7705/HT7706 in unbuffered mode, care must be taken to ensure that the source impedance is low enough not to introduce gain errors in the system. This significantly limits the amount of passive antialiasing filtering which can be provided in front of the HT7705/HT7706 when it is used in unbuffered mode. However, when the part is used in buffered mode, large source impedances will simply result in a small dc offset error (a 10 k\Omega source resistance will cause an offset error of less than 10 μ V). Therefore, if the system requires any significant source impedances to provide passive analog filtering in front of the HT7705/HT7706, it is recommended that the part be operated in buffered mode.

CALIBRATION

The HT7705/HT7706 provides a number of calibration options which can be programmed via the MD1 and MD0 bits of the Setup Register. The different calibration options are outlined in the Setup Register and Calibration Sequences sections. A calibration cycle may be initiated at any time by writing to these bits of the Setup Register. Calibration on the HT7705/HT7706 removes offset and gain errors from the device. A calibration routine should be initiated on the device whenever there is a change in the ambient operating temperature or supply voltage. It should also be initiated if there is a change in the selected gain, filter notch or bipolar/unipolar input range.

The HT7705/HT7706 offers self-calibration and system calibration facilities. For full calibration to occur on the selected channel, the on-chip microcontroller must record the modulator output for two different input conditions. These are "zeroscale" and "full-scale" points. These points are derived by performing a conversion on the different input voltages provided to the input of the modulator during calibration. As a result, the accuracy of the calibration can only be as good as the noise level that it provides in normal mode. The result of the "zero-scale" calibration conversion is stored in the Zero-Scale Calibration Register while the result of the "full-scale" calibration conversion is stored in the Full-Scale Calibration Register. With these readings, the microcontroller can calculate the offset and the gain slope for the input-to-output transfer function of the converter. Internally, the part works with a resolution of 33 bits to determine its conversion result of 16 bits.



Self-Calibration

A self-calibration is initiated on the HT7705/HT7706 by writing the appropriate values (0, 1) to the MD1 and MD0 bits of the Setup Register. In the self-calibration mode with a unipolar input range, the zero scale point used in determining the calibration coefficients is with the inputs of the differential pair internally shorted on the part (i.e., AIN(+) = AIN(-) = Internal Bias Voltage in the case of the HT7705 and AIN = COMMON = Internal Bias voltage on the HT7706). The PGA is set for the selected gain (as per G1 and G0 bits in the Communications Register) for this zero-scale calibration conversion. The full-scale calibration conversion is performed at the selected gain on an internally-generated voltage of V_{REF}/Selected Gain.

The duration time for the calibration is $6 \times 1/0$ utput Rate. This is made up of $3 \times 1/0$ utput Rate for the zero-scale calibration and 3×1 /Output Rate for the full-scale calibration. At this time the MD1 and MD0 bits in the Setup Register return to 0, 0. This gives the earliest indication that the calibration sequence is complete. The DRDY line goes high when calibration is initiated and does not return low until there is a valid new word in the data register. The duration time from the calibration command being issued to *DRDY* going low is 9×1 /Output Rate. This is made up of $3 \times 1/Output$ Rate for the zero-scale calibration, 3×1 /Output Rate for the full-scale calibration, 3×1 /Output Rate for a conversion on the analog input and some overhead to correctly set up the coefficients. If DRDY is low before (or goes low during) the calibration command write to the Setup Register, it may take up to one modulator cycle (MCLK IN/128) before DRDY goes high to indicate that calibration is in progress. Therefore, DRDY should be ignored for up to one modulator cycle after the last bit is written to the Setup Register in the calibration command.

For bipolar input ranges in the self-calibrating mode, the sequence is very similar to that just outlined. In this case, the two points are exactly the same as above but, since the part is configured for bipolar operation, the shorted inputs point is actually midscale of the transfer function.

System Calibration

System calibration allows the HT7705/HT7706 to compensate for system gain and offset errors as well as its own internal errors. System calibration performs the same slope factor calculations as self-calibration, but uses voltage values presented by the system to the AIN inputs for the zero- and full-scale points. Full system calibration requires a two-step process, a ZS System Calibration followed by an FS System Calibration.

For a full system calibration, the zero-scale point must be presented to the converter first. It must be applied to the converter before the calibration step is initiated and remain stable until the step is complete. Once the system zero-scale voltage has been set up, a ZS System Calibration is then initiated by writing the appropriate values (1, 0) to the MD1 and MD0 bits of the Setup Register. The zero-scale system calibration is performed at the selected gain. The duration of the calibration is 3×1 /Output Rate. At this time, the MD1 and MD0 bits in the Setup Register return to 0, 0. This gives the earliest indication that the calibration sequence is complete. The *DRDY* line goes high when calibration is initiated and does not return low until there is a valid new word in the data register. The duration time from the calibration command being issued to *DRDY* going low is 4×1 /Output Rate as the part performs a normal conversion on the AIN voltage before *DRDY* goes low. If *DRDY* is low before (or goes low during) the calibration command write to the Setup Register, it may take up to one modulator cycle (MCLK IN/128) before *DRDY* goes high to indicate that calibration is in progress. Therefore, *DRDY* should be ignored for up to one modulator cycle after the last bit is written to the Setup Register in the calibration command.

After the zero-scale point is calibrated, the full-scale point is applied to AIN and the second step of the calibration process is initiated by again writing the appropriate values (1, 1) to MD1 and MD0. Again, the full-scale voltage must be set up before the calibration is initiated and it must remain stable throughout the calibration step. The full-scale system calibration is performed at the selected gain. The duration of the calibration is 3×1 /Output Rate. At this time, the MD1 and MD0 bits in the Setup Register return to 0, 0. This gives the earliest indication that the calibration sequence is complete. The DRDY line goes high when calibration is initiated and does not return low until there is a valid new word in the data register. The duration time from the calibration command being issued to DRDY going low is $4 \times 1/0$ utput Rate as the part performs a normal conversion on the AIN voltage before DRDY goes low. If DRDY is low before (or goes low during) the calibration command write to the Setup Register, it may take up to one modulator cycle (MCLK IN/128) before DRDY goes high to indicate that calibration is in progress. Therefore, DRDY should be ignored for up to one modulator cycle after the last bit is written to the Setup Register in the calibration command.

In the unipolar mode, the system calibration is performed between the two endpoints of the transfer function; in the bipolar mode, it is performed between midscale (zero differential voltage) and positive full-scale.

The fact that the system calibration is a two-step calibration offers another feature. After the sequence of a full system calibration has been completed, additional offset or gain calibrations can be performed by themselves to adjust the system zero reference point or the system gain. Calibrating one of the parameters, either system offset or system gain, will not affect the other parameter.

System calibration can also be used to remove any errors from source impedances on the analog input when the part is used in unbuffered mode. A simple R, C antialiasing filter on the front end may introduce a gain error on the analog input voltage, but the system calibration can be used to remove this error.

Span and Offset Limits

Whenever a system calibration mode is used, there are limits on the amount of offset and span which can be accommodated. The overriding requirement in determining the amount of offset and gain that can be accommodated by the part is the requirement that the positive full-scale calibration limit is < 1.05 × $V_{\text{REF}}/\text{GAIN}$. This allows the input range to go 5% above the nominal range. The built-in headroom in the HT7705/HT7706's analog modulator ensures that the part will still operate correctly with a positive full-scale voltage that is 5% beyond the nominal.

The range of input span in both the unipolar and bipolar modes has a minimum value of $0.8 \times V_{REF}$ /GAIN and a maximum value of $2.1 \times V_{REF}$ /GAIN. However, the span (which is the difference between the bottom of the HT7705/HT7706's input



range and the top of its input range) has to take into account the limitation on the positive full-scale voltage. The amount of offset which can be accommodated depends on whether the unipolar or bipolar mode is being used. Once again, the offset has to take into account the limitation on the positive full-scale voltage. In unipolar mode, there is considerable flexibility in handling negative (with respect to AIN(–) on the HT7705 and with respect to COMMON on the HT7706) offsets. In both unipolar and bipolar modes, the range of positive offsets that can be handled by the part depends on the selected span. Therefore, in determining the limits for system zero-scale and full-scale calibrations, the user has to ensure that the offset range plus the span range does exceed $1.05 \times V_{REF}/GAIN$. This is best illustrated by looking at a few examples.

If the part is used in unipolar mode with a required span of $0.8 \times V_{\text{REF}}/\text{GAIN}$, the offset range the system calibration can handle is from $-1.05 \times V_{\text{REF}}/\text{GAIN}$ to $+0.25 \times V_{\text{REF}}/\text{GAIN}$. If the part is used in unipolar mode with a required span of $V_{\text{REF}}/$ GAIN, the offset range the system calibration can handle is from $-1.05 \times V_{\text{REF}}/\text{GAIN}$ to $+0.05 \times V_{\text{REF}}/\text{GAIN}$. Similarly, if the part is used in unipolar mode and required to remove an offset of $0.2 \times V_{\text{REF}}/\text{GAIN}$, the span range the system calibration can handle is $0.85 \times V_{\text{REF}}/\text{GAIN}$.

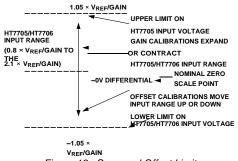


Figure 13. Span and Offset Limits

If the part is used in bipolar mode with a required span of $\pm 0.4 \times V_{REF}$ /GAIN, the offset range the system calibration can handle is from $-0.65 \times V_{REF}$ /GAIN to $+0.65 \times V_{REF}$ /GAIN. If the part is used in bipolar mode with a required span of $\pm V_{REF}$ /GAIN, then the offset range which the system calibration can handle is from $-0.05 \times V_{REF}$ /GAIN to $+0.05 \times V_{REF}$ /GAIN. Similarly, if the part is used in bipolar mode and required to remove an offset of $\pm 0.2 \times V_{REF}$ /GAIN, the span range the system calibration can handle is $\pm 0.85 \times V_{REF}$ /GAIN.

Power-Up and Calibration

On power-up, the HT7705/HT7706 performs an internal reset that sets the contents of the internal registers to a known state. There are default values loaded to all registers after power-on or reset. The default values contain nominal calibration coefficients for the calibration registers. However, to ensure correct calibration for the device, a calibration routine should be performed after power-up.

The power dissipation and temperature drift of the HT7705/ HT7706 are low and no warm-up time is required before the initial calibration is performed. However, if an external reference is being used, this reference must have stabilized before calibration is initiated. Similarly, if the clock source for the part is generated from a crystal or resonator across the MCLK pins, the start-up time for the oscillator circuit should elapse before a calibration is initiated on the part (see below).

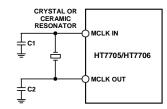


Figure 14. Crystal/Resonator Connection for the HT7705/HT7706

USING THE HT7705/HT7706 Clocking and Oscillator Circuit

The HT7705/HT7706 requires a master clock input, which may be an external CMOS compatible clock signal applied to the MCLK IN pin with the MCLK OUT pin left unconnected. Alternatively, a crystal or ceramic resonator of the correct frequency can be connected between MCLK IN and MCLK OUT as shown in figure 6, in which case the clock circuit will function as an oscillator, providing the clock source for the part. The input sampling frequency, be modulator sampling frequency, the -3 dB frequency, output update rate and calibration time are all directly related to the master clock frequency.

Reducing the master clock frequency by a factor of 2 will halve the above frequencies and update rate and double the calibration time. The current drawn from the V_{DD} power supply is also related to f_{CLKIN} . Reducing f_{CLKIN} by a factor of 2 will halve the digital part of the total V_{DD} current but will not affect the current drawn by the analog circuitry.

Using the part with a crystal or ceramic resonator between the

MCLK IN and MCLK OUT pins generally causes more current to be drawn from V_{DD} than when the part is clocked from a driven clock signal at the MCLK IN pin. This is because the on-chip oscillator circuit is active in the case of the crystal or ceramic resonator. Therefore, the lowest possible current on the HT7705/HT7706 is achieved with an externally applied clock at the MCLK IN pin with MCLK OUT unconnected, unloaded and disabled.

The amount of additional current taken by the oscillator depends on a number of factors-first, the larger the value of capacitor (C1 and C2) placed on the MCLK IN and MCLK OUT pins, the larger the current consumption on the HT7705/ HT7706. Care should be taken not to exceed the capacitor values recommended by the crystal and ceramic resonator manufacturers to avoid consuming unnecessary current. Typical values for C1 and C2 are recommended by crystal or ceramic resonator manufacturers, these are in the range of 30 pF to 50 pF and if the capacitor values on MCLK IN and MCLK OUT are kept in this range they will not result in any excessive current. Another factor that influences the current is the effective series resistance (ESR) of the crystal that appears between the MCLK IN and MCLK OUT pins of the HT7705/HT7706. As a general rule, the lower the ESR value the lower the current taken by the oscillator circuit.



When operating with a clock frequency of 2.4576 MHz, there is 50 μA difference in the current between an externally applied clock and a crystal resonator when operating with a V_{DD} of +3 V. With V_{DD} = +5 V and f_{CLKIN} = 2.4576 MHz, the typical current increases by 250 μA for a crystal/resonator supplied clock versus an externally applied clock. The ESR values for crystals and resonators at this frequency tend to be low and as a result there tends to be little difference between different crystal and resonator types.

When operating with a clock frequency of 1 MHz, the ESR value for different crystal types varies significantly. As a result, the current drain varies across crystal types. When using a crystal with an ESR of 700 Ω or when using a ceramic resonator, the increase in the typical current over an externally-applied clock is 20 μ A with V_{DD} = +3 V and 200 μ A with V_{DD} = +5 V. When using a crystal with an ESR of 3 k Ω , the increase in the typical current over an externally applied clock is again 100 μ A with V_{DD} = +3 V but 400 μ A with V_{DD} = +5 V.

The on-chip oscillator circuit also has a start-up time associated with it before it is oscillating at its correct frequency and correct voltage levels. Typical start-up times with V_{DD} = 5 V are 6 ms using a 4.9512 MHz crystal, 16 ms with a 2.4576 MHz crystal and 20 ms with a 1 MHz crystal oscillator. Start-up times are typically 20% slower when the power supply voltage is reduced to 3 V. At 3 V supplies, depending on the loading capacitances on the MCLK pins, a 1 M\Omega feedback resistor may be required across the crystal or resonator in order to keep the start up times around the 20 ms duration.

The HT7705/HT7706's master clock appears on the MCLK OUT pin of the device. The maximum recommended load on this pin is one CMOS load. When using a crystal or ceramic resonator to generate the HT7705/HT7706's clock, it may be desirable to use this clock as the clock source for the system. In this case, it is recommended that the MCLK OUT signal is buffered with a CMOS buffer before being applied to the rest of the circuit.

System Synchronization

The FSYNC bit of the Setup Register allows the user to reset the modulator and digital filter without affecting any of the setup conditions on the part. This allows the user to start gathering samples of the analog input from a known point in time, i.e., when the FSYNC is changed from 1 to 0.

With a 1 in the FSYNC bit of the Setup Register, the digital filter and analog modulator are held in a known reset state and the part is not processing any input samples. When a 0 is then written to the FSYNC bit, the modulator and filter are taken out of this reset state and the part starts to gather samples again on the next master clock edge.

The FSYNC input can also be used as a software start convert command allowing the HT7705/HT7706 to be operated in a conventional converter fashion. In this mode, writing to the FSYNC bit starts conversion and the falling edge of *DRDY* indicates when conversion is complete. The disadvantage of this scheme is that the settling time of the filter has to be taken into account for every data register update. This means that the rate at which the data register is updated is three times slower in this mode. Since the FSYNC bit resets the digital filter, the full settling time of $3 \times 1/0$ utput Rate has to elapse before there is a new word loaded to the output register on the part. If the *DRDY* signal is low when FSYNC goes to a 0, the *DRDY* signal will not be reset high by the FSYNC command. This is because the HT7705/HT7706 recognizes that there is a word in the data register which has not been read. The *DRDY* line will stay low until an update of the data register takes place, at which time it will go high for $500 \times t_{CLKIN}$ before returning low again. A read from the data register resets the *DRDY* signal high and it will not return low until the settling time of the filter has elapsed (from the FSYNC command) and there is a valid new word in the data register. If the *DRDY* line is high when the FSYNC command is issued, the *DRDY* line will not return low until the settling time of the filter has elapsed.

Reset Input

The *RESET* input on the HT7705/HT7706 resets all the logic, the digital filter and the analog modulator, while all on-chip registers are reset to their default state. *DRDY* is driven high and the HT7705/HT7706 ignores all communications to any of its registers while the *RESET* input is low. When the *RESET* input returns high, the HT7705/HT7706 starts to process data and *DRDY* will return low in $3 \times 1/0$ utput Rate indicating a valid new word in the data register. However, the HT7705/HT7706 for a *RESET* and it is generally necessary to set up all registers and carry out a calibration after a *RESET* command.

The HT7705/HT7706's on-chip oscillator circuit continues to function even when the *RESET* input is low. The master clock signal continues to be available on the MCLK OUT pin. Therefore, in applications where the system clock is provided by the HT7705/HT7706's clock, the HT7705/HT7706 produces an uninterrupted master clock during *RESET* commands.

Standby Mode

The STBY bit in the Communications Register of the HT7705/ HT7706 allows the user to place the part in a power-down mode when it is not required to provide conversion results. The HT7705/HT7706 retains the contents of all its on-chip registers (including the data register) while in standby mode. When released from standby mode, the part starts to process data and a new word is available in the data register in $3 \times 1/0$ utput rate from when a 0 is written to the STBY bit.

The STBY bit does not affect the digital interface, nor does it affect the status of the *DRDY* line. If *DRDY* is high when the STBY bit is brought low, it will remain high until there is a valid new word in the data register. If *DRDY* is low when the STBY bit is brought low, it will remain low until the data register is updated, at which time the *DRDY* line will return high for $500 \times t_{CLKIN}$ before returning low again. If *DRDY* is low when the part enters its standby mode (indicating a valid unread word in the data register), the data register can be read while the part is in standby. At the end of this read operation, the *DRDY* will be reset high as normal.



Placing the part in standby mode reduces the total current to 9 μ A typical with V_{DD} = 5 V and 4 μ A with V_{DD} = 3 V when the part is operated from an external master clock provided this master clock is stopped. If the external clock continues to run in standby mode, the standby current increases to 150 μ A typical with 5 V supplies and 75 μ A typical with 3.3 V supplies. If a crystal or ceramic resonator is used as the clock source, the total current in standby mode is 400 μ A typical with 5 V supplies and 90 μ A with 3.3 V supplies. This is because the on-chip oscillator circuit continues to run when the part is in its standby mode. This is important in applications where the system clock is provided by the HT7705/HT7706's clock, so that the HT7705/HT7706 produces an uninterrupted master clock even when it is in its standby mode.

Accuracy

Sigma-Delta ADCs, like VFCs and other integrating ADCs, do not contain any source of nonmonotonicity and inherently offer no missing codes performance. The HT7705/HT7706 achieves excellent linearity by the use of high quality, on-chip capacitors, which have a very low capacitance/voltage coefficient. The device also achieves low input drift through the use of chopper-stabilized techniques in its input stage. To ensure excellent performance over time and temperature, the HT7705/HT7706 uses digital calibration techniques that minimize offset and gain error.

Drift Considerations

The HT7705/HT7706 uses chopper stabilization techniques to minimize input offset drift. Charge injection in the analog switches and dc leakage currents at the sampling node are the primary sources of offset voltage drift in the converter. The dc input leakage current is essentially independent of the selected gain. Gain drift within the converter depends primarily upon the temperature tracking of the internal capacitors. It is not affected by leakage currents.

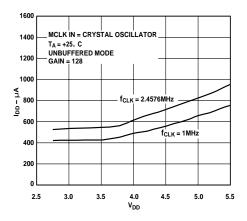
Measurement errors due to offset drift or gain drift can be eliminated at any time by recalibrating the converter. Using the system calibration mode can also minimize offset and gain errors in the signal conditioning circuitry. Integral and differential linearity errors are not significantly affected by temperature changes.

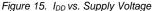
POWER SUPPLIES

The HT7705/HT7706 operates with a V_{DD} power supply between 2.7 V and 5.25 V. While the latch-up performance of the HT7705/HT7706 is good, it is important that power is applied to the HT7705/HT7706 before signals at REF IN, AIN or the logic input pins in order to avoid excessive currents. If this is not possible, the current that flows in any of these pins should be limited. If separate supplies are used for the HT7705/HT7706 should be powered up first. If it is not possible to guarantee this, current limiting resistors should be placed in series with the logic inputs to again limit the current. Latch-up current is greater than 100 mA.

Supply Current

The current consumption on the HT7705/HT7706 is specified for supplies in the range +2.7 V to +3.3 V and in the range +4.75 V to +5.25 V. The part operates over a +2.7 V to +5.25 V supply range and the I_{DD} for the part varies as the supply voltage varies over this range. There is an internal current boost bit on the HT7705/HT7706 that is set internally in accordance with the operating conditions. This affects the current drawn by the analog circuitry within these devices. Minimum power consumption is achieved when the HT7705/HT7706 is operated with an f_{CLKIN} of 1 MHz or at gains of 1 to 4 with f_{CLKIN} = 2.4575 MHz as the internal boost bit is off reducing the analog current consumption. Figure 15 shows the variation of the typical I_{DD} with V_{DD} voltage for both a 1 MHz crystal oscillator and a 2.4576 MHz crystal oscillator at +25°C. The HT7705/HT7706 is operated in unbuffered mode. The relationship shows that the IDD is minimized by operating the part with lower V_{DD} voltages. I_{DD} on the HT7705/HT7706 is also minimized by using an external master clock or by optimizing external components when using the on-chip oscillator circuit. Figures 3, 4, 6 and 7 show variations in I_{DD} with gain, V_{DD} and clock frequency using an external clock.





Grounding and Layout

Since the analog inputs and reference input are differential, most of the voltages in the analog modulator are common-mode voltages. The excellent common-mode rejection of the part will remove common-mode noise on these inputs. The digital filter will provide rejection of broadband noise on the power supplies, except at integer multiples of the modulator sampling frequency. The digital filter also removes noise from the analog and reference inputs provided those noise sources do not saturate the analog modulator. As a result, the HT7705/HT7706 is more immune to noise interference than a conventional high resolution converter. However, because the resolution of the HT7705/ HT7706 is so high, and the noise levels from the HT7705/ HT7706 so low, care must be taken with regard to grounding and layout.





The printed circuit board that houses the HT7705 should be designed so that the analog and digital sections are separated and confined to certain areas of the board. This facilitates the use of ground planes which can be separated easily. A minimum etch technique is generally best for ground planes as it gives the best shielding. Digital and analog ground planes should only be joined in one place to avoid ground loops. If the HT7705/HT7706 is in a system where multiple devices require AGND-to-DGND connections, the connection should be made at one point only, a star ground point which should be established as close as possible to the HT7705 GND.

Avoid running digital lines under the device as these will couple noise onto the die. The analog ground plane should be allowed to run under the HT7705/HT7706 to avoid noise coupling. The power supply lines to the HT7705/HT7706 should use as large a trace as possible to provide low impedance paths and reduce the effects of glitches on the power supply line. Fast switching signals like clocks should be shielded with digital ground to avoid radiating noise to other sections of the board and clock signals should never be run near the analog inputs. Avoid crossover of digital and analog signals. Traces on opposite sides of the board should run at right angles to each other. This will reduce the effects of feedthrough through the board. A microstrip technique is by far the best, but is not always possible with a double-sided board. In this technique, the component side of the board is dedicated to ground planes while signals are placed on the solder side.

Good decoupling is important when using high resolution ADCs. All analog supplies should be decoupled with 10 μF tantalum in parallel with 0.1 μF ceramic capacitors to GND. To achieve the best from these decoupling components, they have to be placed as close as possible to the device, ideally right up against the device. All logic chips should be decoupled with 0.1 μF disc ceramic capacitors to DGND.

Evaluating the HT7705/HT7706 Performance

The recommended layout for the HT7705 and HT7706 is outlined in their associated evaluation. These evaluation board packages include a fully assembled and tested evaluation board, documentation, software for controlling the board over the printer port of a PC and software for analyzing their performance on the PC.

Noise levels in the signals applied to the HT7705/HT7706 may also affect performance of the part. The HT7705/HT7706 software evaluation package allows the user to evaluate the true performance of the part, independent of the analog input signal. The scheme involves using a test mode on the part where the inputs to the HT7705 are internally shorted together to provide a zero differential voltage for the analog modulator. External to the device, the AIN1(-) input on the HT7705 should be connected to a voltage that is within the allowable common-mode range of the part. Similarly, on the HT7706 the COMMON input should be connected to a voltage within its allowable common-mode range for evaluation purposes. This scheme should be used after a calibration has been performed on the part.

DIGITAL INTERFACE

As previously outlined, the HT7705/HT7706's programmable functions are controlled using a set of on-chip registers. Data is written to these registers via the part's serial interface and read access to the on-chip registers is also provided by this interface. All communications to the part must start with a write operation to the Communications Register. After power-on or RESET, the device expects a write to its Communications Register. The data written to this register determines whether the next operation to the part is a read or a write operation and also determines to which register this read or write operation occurs. Therefore, write access to any of the other registers on the part starts with a write operation to the Communications Register followed by a write to the selected register. A read operation from any other register on the part (including the output data register) starts with a write operation to the Communications Register followed by a read operation from the selected register.

The HT7705/HT7706's serial interface consists of five signals. CS, SCLK, DIN, DOUT and DRDY. The DIN line is used for transferring data into the on-chip registers while the DOUT line is used for accessing data from the on-chip registers. SCLK is the serial clock input for the device and all data transfers (either on DIN or DOUT) take place with respect to this SCLK signal. The DRDY line is used as a status signal to indicate when data is ready to be read from the HT7705/HT7706's data register. DRDY goes low when a new data word is available in the output register. It is reset high when a read operation from the data register is complete. It also goes high prior to the updating of the output register to indicate when not to read from the device to ensure that a data read is not attempted while the register is being updated. CS is used to select the device. It can be used to decode the HT7705/HT7706 in systems where a number of parts are connected to the serial bus.



Figures 16 and 17 show timing diagrams for interfacing to the HT7705/HT7706 with *CS* used to decode the part. Figure 16 is for a read operation from the HT7705/HT7706's output shift register while Figure 17 shows a write operation to the input shift register. It is possible to read the same data twice from the output register even though the *DRDY* line returns high after the first read operation. Care must be taken, however, to ensure that the read operations have been completed before the next output update is about to take place.

The HT7705/HT7706 serial interface can operate in three-wire mode by tying the *CS* input low. In this case, the SCLK, DIN and DOUT lines are used to communicate with the HT7705/HT7706 and the status of *DRDY* can be obtained by interrogating the MSB of the Communications Register. This scheme is suitable for interfacing to microcontrollers. If *CS* is required as a decoding signal, it can be generated from a port bit. For microcontroller interfaces, it is recommended that the SCLK idles high between data transfers.

The HT7705/HT7706 can also be operated with *CS* used as a frame synchronization signal. This scheme is suitable for DSP interfaces. In this case, the first bit (MSB) is effectively clocked out by *CS* since *CS* would normally occur after the falling edge of SCLK in DSPs. The SCLK can continue to run between data transfers provided the timing numbers are obeyed.

The serial interface can be reset by exercising the *RESET* input on the part. It can also be reset by writing a series of 1s on the DIN input. If a Logic 1 is written to the HT7705/HT7706 DIN line for at least 32 serial clock cycles the serial interface is reset. This ensures that in three-wire systems, if the interface gets lost either via a software error or by some glitch in the system, it can be reset back to a known state. This state returns the interface to where the HT7705/HT7706 is expecting a write operation to its Communications Register. This operation in itself does not reset the contents of any registers but since the interface was lost, the information written to any of the registers is unknown and it is advisable to set up all registers again.

Some microprocessor or microcontroller serial interfaces have a single serial data line. In this case, it is possible to connect the HT7705/HT7706's DATA OUT and DATA IN lines together and connect them to the single data line of the processor. A 10 kQ pull-up resistor should be used on this single data line. In this case, if the interface gets lost, because the read and write operations share the same line the procedure to reset it back to a known state is somewhat different than previously described. It requires a read operation of 24 serial clocks followed by a write operation where a Logic 1 is written for at least 32 serial clock cycles to ensure that the serial interface is back into a known state.

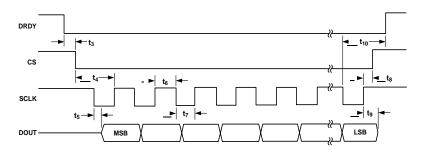


Figure 16. Read Cycle Timing Diagram

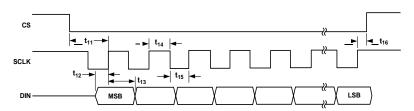


Figure 17. Write Cycle Timing Diagram



CONFIGURING THE HT7705/HT7706

The HT7705/HT7706 contains six on-chip registers that the user can accesses via the serial interface. Communication with any of these registers is initiated by writing to the Communications Register first. Figure 18 outlines a flow diagram of the sequence used to configure all registers after a power-up or reset on the HT7705, similar procedures apply to the HT7706. The flowchart also shows two different read options—the first where

the *DRDY* pin is polled to determine when an update of the data register has taken place, the second where the *DRDY* bit of the Communications Register is interrogated to see if a data register update has taken place. Also included in the flowing diagram is a series of words that should be written to the registers for a particular set of operating conditions. These conditions are gain of one, no filter sync, bipolar mode, buffer off, clock of 4.9512 MHz and an output rate of 50 Hz.

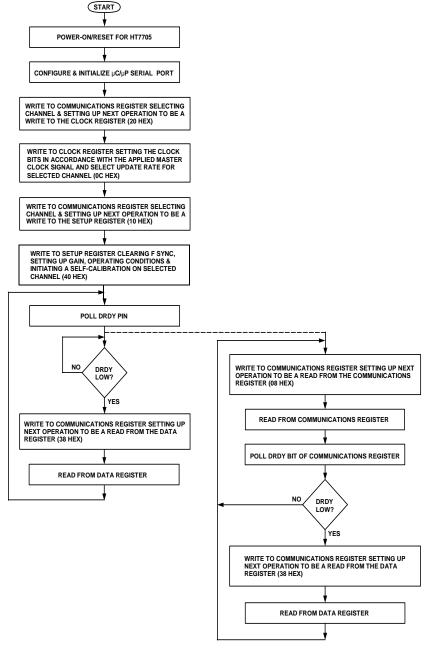


Figure 18. Flowchart for Setting Up and Reading from the HT7705





MICROCOMPUTER/MICROPROCESSOR INTERFACING

The HT7705/HT7706's flexible serial interface allows for easy interface to most microcomputers and microprocessors. The flowchart of Figure 10 outlines the sequence that should be followed when interfacing a microcontroller or microprocessor to the HT7705/HT7706. Figures 19, 20 and 21 show some typical interface circuits.

The serial interface on the HT7705/HT7706 is capable of operating from just three wires and is compatible with SPI interface protocols. The three-wire operation makes the part ideal for isolated systems where minimizing the number of interface lines minimizes the number of opto-isolators required in the system. The serial clock input is a Schmitt triggered input to accommodate slow edges from opto-couplers. The rise and fall times of other digital inputs to the HT7705/HT7706 should be no longer than 1 μ s.

Most of the registers on the HT7705/HT7706 are 8-bit registers, which facilitates easy interfacing to the 8-bit serial ports of microcontrollers. The Data Register on the HT7705/HT7706 is 16 bits, and the offset and gain registers are 24-bit registers but data transfers to these registers can consist of multiple 8-bit transfers to the serial port of the microcontroller. DSP processors and microprocessors generally transfer 16 bits of data in a serial data operation. Some of these processors, such as the ADSP-2105, have the facility to program the amount of cycles in a serial transfer. This allows the user to tailor the number of bits in any transfer to match the register length of the required register in the HT7705/HT7706.

Even though some of the registers on the HT7705/HT7706 are only eight bits in length, communicating with two of these registers in successive write operations can be handled as a single 16bit data transfer if required. For example, if the Setup Register is to be updated, the processor must first write to the Communications Register (saying that the next operation is a write to the Setup Register) and then write eight bits to the Setup Register. If required, this can all be done in a single 16-bit transfer because once the eight serial clocks of the write operation to the Communications Register have been completed, the part immediately sets itself up for a write operation to the Setup Register.

HT7705/HT7706 to 68HC11 Interface

Figure 19 shows an interface between the HT7705/HT7706 and the 68HC11 microcontroller. The diagram shows the minimum (three-wire) interface with CS on the HT7705/HT7706 hardwired low. In this scheme, the DRDY bit of the Communications Register is monitored to determine when the Data Register is updated. An alternative scheme, which increases the number of interface lines to four, is to monitor the DRDY output line from the HT7705/HT7706. The monitoring of the DRDY line can be done in two ways. First, DRDY can be connected to one of the 68HC11's port bits (such as PC0), which is configured as an input. This port bit is then polled to determine the status of DRDY. The second scheme is to use an interrupt driven system, in which case the DRDY output is connected to the IRQ input of the 68HC11. For interfaces that require control of the CS input on the HT7705/HT7706, one of the port bits of the 68HC11 (such as PC1), which is configured as an output, can be used to drive the CS input.

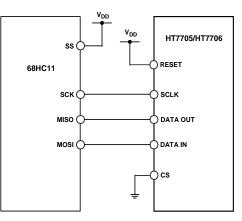


Figure 19. HT7705/HT7706 to 68HC11 Interface

The 68HC11 is configured in the master mode with its CPOL bit set to a logic one and its CPHA bit set to a logic one. When the 68HC11 is configured like this, its SCLK line idles high between data transfers. The HT7705/HT7706 is not capable of full duplex operation. If the HT7705/HT7706 is configured for a write operation, no data appears on the DATA OUT lines even when the SCLK input is active. Similarly, if the HT7705/HT7706 is configured for a read operation, data presented to the part on the DATA IN line is ignored even when SCLK is active.

Coding for an interface between the 68HC11 and the HT7705/ HT7706 is given in Table XV. In this example, the *DRDY* output line of the HT7705/HT7706 is connected to the PC0 port bit of the 68HC11 and is polled to determine its status.

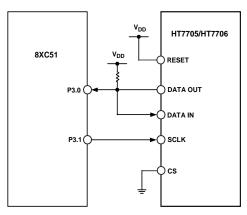


Figure 20. HT7705/HT7706 to 8XC51 Interface

HT7705/HT7706 to 8051 Interface

An interface circuit between the HT7705/HT7706 and the 8XC51 microcontroller is shown in Figure 20. The diagram shows the minimum number of interface connections with *CS* on the HT7705/HT7706 hard-wired low. In the case of the 8XC51 interface the minimum number of interconnects is just two. In this scheme, the *DRDY* bit of the Communications Register is monitored to determine when the Data Register is updated. The alternative scheme, which increases the number of





interface lines to three, is to monitor the DRDY output line from the HT7705/HT7706. The monitoring of the DRDY line can be done in two ways. First, DRDY can be connected to one of the 8XC51's port bits (such as P1.0) which is configured as an input. This port bit is then polled to determine the status of DRDY. The second scheme is to use an interrupt-driven system, in which case the DRDY output is connected to the INT1 input of the 8XC51. For interfaces that require control of the CS input on the HT7705/HT7706, one of the port bits of the 8XC51 (such as P1.1), which is configured as an output, can be used to drive the CS input. The 8XC51 is configured in its Mode 0 serial interface mode. Its serial interface contains a single data line. As a result, the DATA OUT and DATA IN pins of the HT7705/HT7706 should be connected together with a 10 k Ω pull-up resistor. The serial clock on the 8XC51 idles high between data transfers. The 8XC51 outputs the LSB first in a write operation, while the HT7705/HT7706 expects the MSB first so the data to be transmitted has to be rearranged before being written to the output serial register. Similarly, the HT7705/HT7706 outputs the MSB first during a read operation while the 8XC51 expects the LSB first. Therefore, the data read into the serial buffer needs to be rearranged before the correct data word from the HT7705/HT7706 is available in the accumulator.

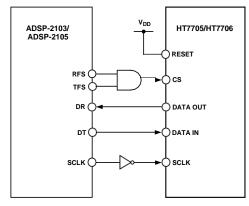


Figure 21. HT7705/HT7706 to ADSP-2103/ADSP-2105 Interface

HT7705/HT7706 to ADSP-2103/ADSP-2105 Interface

Figure 21 shows an interface between the HT7705/HT7706 and the ADSP-2103/ADSP-2105 DSP processor. In the interface shown, the *DRDY* bit of the Communications Register is again monitored to determine when the Data Register is updated. The alternative scheme is to use an interrupt-driven system, in which case the *DRDY* output is connected to the IRQ2 input of the ADSP-2103/ADSP-2105. The serial interface of the ADSP-2103/ADSP-2105 is set up for alternate framing mode. The *RFS* and *TFS* pins of the ADSP-2103/ADSP-2105 are configured as active low outputs and the ADSP-2103/ADSP-2105 serial clock line, SCLK, is also configured as an output. The *CS* for the HT7705/HT7706 is active when either the *RFS* or *TFS* outputs from the ADSP-2103/ADSP-2105 should be limited to 3 MHz to ensure correct operation with the HT7705/HT7706.

CODE FOR SETTING UP THE HT7705/HT7706

Table XVII gives a set of read and write routines in C code for interfacing the 68HC11 microcontroller to the HT7705. The sample program sets up the various registers on the HT7705 and reads 1000 samples from the part into the 68HC11. The setup conditions on the part are exactly the same as those outlined for the flowchart of Figure 18. In the example code given here, the *DRDY* output is polled to determine if a new valid word is available in the data register. The very same sequence is applicable for the HT7706.

The sequence of the events in this program are as follows:

- 1. Write to the Communications Register, selecting channel one as the active channel and setting the next operation to be a write to the clock register.
- 2. Write to Clock Register setting the CLK DIV bit which divides the external clock internally by two. This assumes that the external crystal is 4.9512 MHz. The update rate is selected to be 50 Hz.
- 3. Write to Communication Register selecting Channel 1 as the active channel and setting the next operation to be a write to the SetupRegister.
- 4. Write to the Setup Register, setting the gain to 1, setting bipolar mode, buffer off, clearing the filter synchronization and initiating a self-calibration.
- 5. Poll the *DRDY* output.
- 6. Read the data from the Data Register.
- 7. Loop around doing Steps 5 and 6 until the specified number of samples have been taken from the selected channel.





Table XVII. C Code for Interfacing HT7705 to 68HC11

```
/* This program has read and write routines for the 68HC11 to interface to the HT7705 and the sample program sets the various
registers and then reads 1000 samples from one channel. */
#include <math.h>
#include <io6811.h>
#define NUM_SAMPLES 1000 /* change the number of data samples */
#define MAX_REG_LENGTH 2 /* this says that the max length of a register is 2 bytes */
Writetoreg (int);
Read (int,char);
char *datapointer = store;
char store[NUM_SAMPLES*MAX_REG_LENGTH + 30];
void main()
{
           /* the only pin that is programmed here from the 68HC11 is the /CS and this is why the PC2 bit of PORTC is made as
an output */
char a;
DDRC = 0x04; /* PC2 is an output the rest of the port bits are inputs */
PORTC | = 0x04; /* make the /CS line high */
Writetoreg(0x20); /* Active Channel is Ain1(+)/Ain1(-), next operation as write to the clock register */
Writetoreg(0x0C); /* master clock enabled, 4.9512MHz Clock, set output rate to 50Hz*/
Writetoreg(0x10); /* Active Channel is Ain1(+)/Ain1(-), next operation as write to the setup register */
Writetoreg(0x40); /* gain = 1, bipolar mode, buffer off, clear FSYNC and perform a Self Calibration*/
while(PORTC & 0x10); /* wait for /DRDY to go low */
for(a=0;a<NUM_SAMPLES;a++);</pre>
           Writetoreg(0x38); /*set the next operation for 16 bit read from the data register */
           Read(NUM_SAMPES,2);
           }
Writetoreg(int byteword);
{
int q;
SPCR = 0x3f;
SPCR = 0X7f; /* this sets the WiredOR mode(DWOM=1), Master mode(MSTR=1), SCK idles high(CPOL=1), /SS can be low
always (CPHA=1), lowest clock speed(slowest speed which is master clock /32 */
DDRD = 0x18; /* SCK, MOSI outputs */
q = SPSR;
q = SPDR; /* the read of the staus register and of the data register is needed to clear the interrupt which tells the user that the
data transfer is complete */
PORTC &= 0xfb; /* /CS is low */
SPDR = byteword; /* put the byte into data register */
while(!(SPSR & 0x80)); /* wait for /DRDY to go low */
PORTC |= 0x4; /* /CS high */
Read(int amount, int reglength)
{
int q;
SPCR = 0x3f;
SPCR = 0x7f; /* clear the interupt */
DDRD = 0x10; /* MOSI output, MISO input, SCK output */
while(PORTC & 0x10); /* wait for /DRDY to go low */
PORTC & 0xfb ; /* /CS is low */
for(b=0;b<reglength;b++)</pre>
           SPDR = 0;
           while(!(SPSR & 0x80)); /* wait until port ready before reading */
           *datapointer++=SPDR; /* read SPDR into store array via datapointer */
PORTC|=4; /* /CS is high */
}
```



APPLICATIONS

The HT7705 provides a dual channel, low cost, high resolution analog-to-digital function. Because the analog-to-digital function is provided by a sigma-delta architecture, it makes the part more immune to noisy environments thus making the part ideal for use in industrial and process control applications. It also provides a programmable gain amplifier, a digital filter and calibration options. Thus, it provides far more system level functionality than off-the-shelf integrating ADCs without the disadvantage of having to supply a high quality integrating capacitor. In addition, using the HT7705 in a system allows the system designer to achieve a much higher level of resolution because noise performance of the HT7705 is better than that of the integrating ADCs.

The on-chip PGA allows the HT7705 to handle an analog input voltage range as low as 10 mV full-scale with V_{REF} = +1.25 V. The differential inputs of the part allow this analog input range to have an absolute value anywhere between GND and V_{DD} when the part is operated in unbuffered mode. It allows the user to connect the transducer directly to the input of the HT7705. The programmable gain front end on the HT7705 allows the part to handle unipolar analog input ranges from 0 mV to +20 mV to 0 V to +2.5 V and bipolar inputs of \pm 20 mV to \pm 2.5 V. Because the part operates from a single supply these bipolar ranges are with respect to a biased-up differential input.

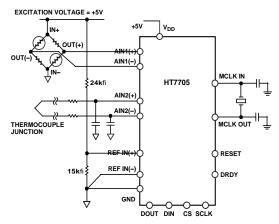


Figure 22. Pressure Measurement Using the HT7705

Pressure Measurement

One typical application of the HT7705 is pressure measurement. Figure 22 shows the HT7705 used with a pressure transducer, the BP01 from Sensym. The pressure transducer is arranged in a bridge network and gives a differential output voltage between its OUT(+) and OUT(-) terminals. With rated full-scale pressure (in this case 300 mmHg) on the transducer, the differential output voltage is 3 mV/V of the input voltage (i.e., the voltage between its IN(+) and IN(-) terminals). Assuming a 5 V excitation voltage, the full-scale output range from the transducer is 15 mV. The excitation voltage for the bridge is also used to generate the reference voltage for the HT7705. Therefore, variations in the excitation voltage do not introduce errors in the system. Choosing resistor values of 24 k Ω and 15 k Ω , as per Figure 22, gives a 1.92 V reference voltage for the HT7705 when the excitation voltage is 5 V. Using the part with a programmed gain of 128 results in the full-scale input span of the HT7705 being 15 mV, which corresponds with the output span from the transducer. The second channel on the HT7705 can be used as an auxiliary channel to measure asecondary variable such as temperature as shown in Figure 22. This secondary channel can be used as a means of adjusting the output of the primary channel, thus removing temperature effects in the system.

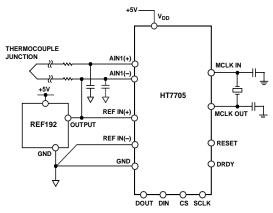


Figure 23. Temperature Measurement Using the HT7705

Temperature Measurement

Another application area for the HT7705 is in temperature measurement. Figure 23 outlines a connection from a thermocouple to the HT7705. In this application, the HT7705 isoperated in its buffered mode to allow large decoupling capacitors on the front end to eliminate any noise pickup that may have been in the thermocouple leads. When the HT7705 is operated in buffered mode, it has a reduced common-mode range. In order to place the differential voltage from the thermocouple on a suitable common-mode voltage, the AIN1(-) input of the HT7705 is biased up at the reference voltage, +2.5 V.

Figure 23 shows another temperature measurement application for the HT7705. In this case, the transducer is an RTD (Resistive Temperature Device), a PT100. The arrangement is a 4-lead RTD configuration. There are voltage drops across the lead resistances R₁₁ and R₁₄ but these simply shift the commonmode voltage. There is no voltage drop across lead resistances R_{L2} and R_{L3} as the input current to the HT7705 is very low. The lead resistances present a small source impedance so it would not generally be necessary to turn on the buffer on the HT7705. If the buffer is required, the common-mode voltage should be set accordingly by inserting a small resistance between the bottom end of the RTD and GND of the HT7705. In the application shown, an external 400 µA current source provides the excitation current for the PT100 and also generates the reference voltage for the HT7705 via the 6.25 k Ω resistor. Variations in the excitation current do not affect the circuit as both the input voltage and the reference voltage vary radiometrically with the excitation current. However, the 6.25 k Ω resistor must have a low temperature coefficient to avoid errors in the reference voltage over temperature.





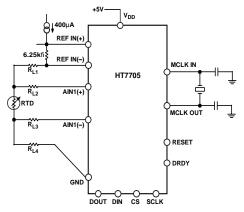


Figure 24. RTD Measurement Using the HT7705

Smart Transmitters

Another area where the low power, single supply, three-wire interface capabilities is of benefit is in smart transmitters. Here, the entire smart transmitter must operate from the 4 mA to 20 mA loop. Tolerances in the loop mean that the amount of current available to power the transmitter is as low as 3.5 mA. The HT7705 consumes only 320 μ A, leaving at least 3 mA available for the rest of the transmitter. Figure 25 shows a block diagram of a smart transmitter which includes the HT7705. The HT7705 with its dual input channel is ideally suited to systems requiring an auxiliary channel whose measured variable is used to correct that of the primary channel.

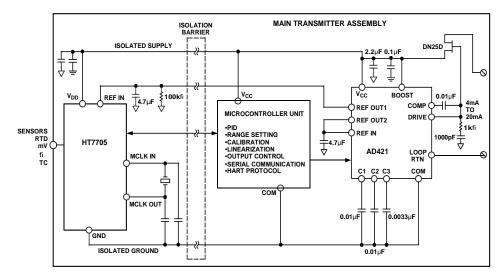


Figure 25. Smart Transmitter Using the HT7705



Battery Monitoring

Another area where the low power, single supply operation is a requirement is battery monitoring in portable equipment applications. Figure 26 shows a block diagram of a battery monitor that includes the HT7705 and an external multiplexer used to differentially measure the voltage across a single cell. The second channel on the HT7705 is used to monitor current drain from the battery. The HT7705 with its dual input channel is ideally suited to measurement systems requiring two input channels, as in this case, to monitor voltage and current. Since the HT7705 can accommodate very low input signals the R_{SENSE}

can be kept low reducing undesired power dissipation. Operating with a gain of 128, a \pm 9.57 mV full-scale signal can be measured with a resolution of 2 μ V, giving 13.5 bits of flicker-free performance in such a system. In order to obtain specified performance in unbuffered mode, the common mode range of the input is from GND to V_{DD} provided that the absolute value of the analog input voltage lies between GND – 30 mV and V_{DD} + 30 mV. Absolute voltages of GND – 200 mV can be accommodated on the HT7705 at 25°C without any degradation in performance, but leakage current increases significantly at elevated temperatures.

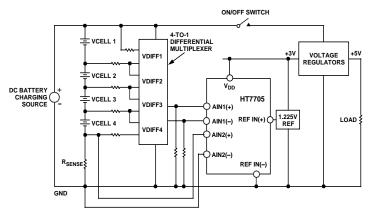
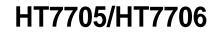


Figure 26. Battery Monitoring Using the HT7705

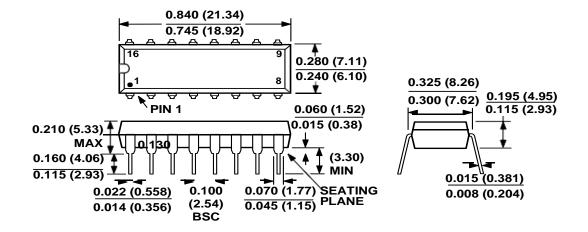




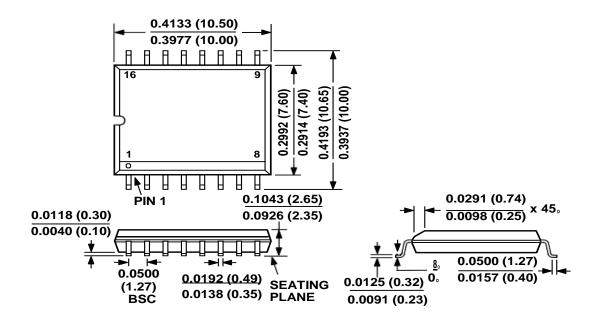
OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

16-Pin Plastic DIP



16-Lead WSOP



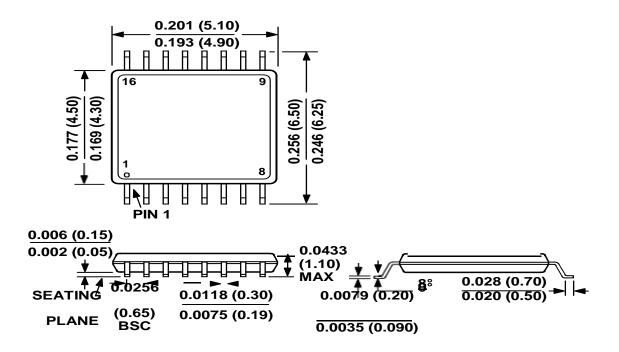




OUTLINE DIMENSIONS

Dimensions shown in inches and (mm).

16-Lead TSSOP



16-Lead SOP

